

Five to Ten Series Cell Lithium-Ion or Lithium-Polymer Battery Protector and Analog Front End

FEATURES

- 5, 6, 7, 8, 9, or 10 Series-Cell Primary Protection
- PMOS FET Drive for Charge and Discharge FETs
- Capable of Operation with 1-mΩ Sense Resistor
- Supply Voltage Range from 7 V to 50 V
- Low Supply Current of 450 μA Typical
- Integrated 5-V, 25-mA LDO
- Integrated 3.3-V, 25-mA LDO
- Stand-Alone Mode
 - Pack Protection Control and Recovery
 - Individual Cell Monitoring
 - Integrated Cell Balancing
 - Programmable Threshold and Delay Time for
 - Overvoltage
 - Undervoltage
 - Overcurrent in Discharge
 - Short Circuit in Discharge
 - Fixed Overtemperature Protection
- Host Control Mode
 - I²C Interface to Host Controller
 - Analog Interface for Host Cell Measurement and System Charge/Discharge Current
 - Host-Controlled Protection Recovery
 - Host-Controlled Cell Balancing

APPLICATIONS

- Cordless Power Tools
- Power Assisted Bicycle/Scooter
- Uninterruptible Power Supply (UPS) Systems
- Medical Equipment
- Portable Test Equipment

DESCRIPTION

The bq77PL900 is a five to ten series cell lithium-ion battery pack protector. The integrated I²C communications interface allows the bq77PL900 also to be as an analog front end (AFE) for a Host controller. Two LDOs, one 5-V, 25-mA and one 3.3-V, 25-mA, are also included and may be used to power a host controller or support circuitry.

The bq77PL900 integrates a voltage translation system to extract battery parameters such as individual cell voltages and charge/discharge current. Variables such as voltage protection thresholds and detection delay times can be programmed by using the internal EEPROM.

The bq77PL900 can act as a stand-alone self-contained battery protection system (stand-alone mode). It can alternatively be combined with a host microcontroller to offer fuel gauge or other battery management capabilities to the host system (host-control mode).

The bq77PL900 provides full safety protection for overvoltage, undervoltage, overcurrent in discharge, and short circuit in discharge conditions. When the EEPROM programmable safety thresholds are reached, the bq77PL900 turns off the FET drive autonomously. No external components are needed to configure the protection features.

The analog front end (AFE) outputs allow a host controller to observe individual cell voltages and charge/discharge currents. The host controller's analog-to-digital converter connects to the bq77PL900 to acquire these values.

Cell balancing can be performed autonomously, or the host controller can activate it individually via a cell bypass path integrated into the bq77PL900. Internal control registers accessible via the $\rm I^2C$ interface configure this operation. The maximum balancing bypass current is set via an external series resistor and the internal FET-on resistance (typically 400 Ω). Optionally, external bypass cell balance FETs can be used for increased current capability.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

TYPICAL IMPLEMENTATION

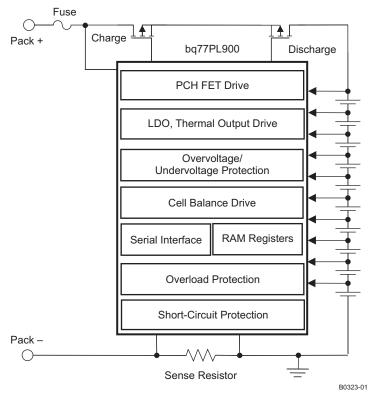


Figure 1. Stand-Alone Mode



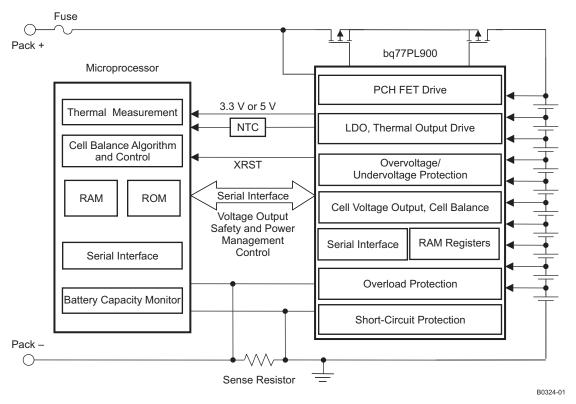


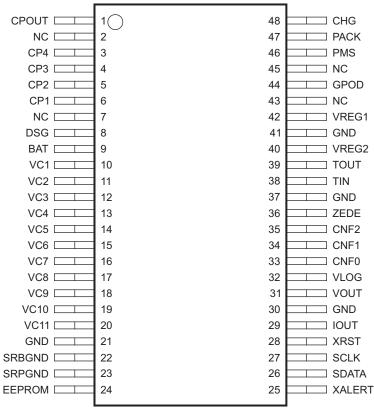
Figure 2. Host-Control Mode



PIN DETAILS

Pin Out Diagram

DL Package (Top View)



P0084-01

TERMINAL FUNCTIONS

| NAME | PIN# | DESCRIPTION |
|--------|------------|------------------------------------------------------------------------------------------|
| BAT | 9 | Power supply voltage |
| CHG | 48 | Charge FET gate drive |
| CNF0 | 33 | Used cell for number determination in combination with CNF1 and CNF2 |
| CNF1 | 34 | Used cell for number determination in combination with CNF0 and CNF2 |
| CNF2 | 35 | Used cell for number determination in combination with CNF0 and CNF1 |
| CP1 | 6 | Charge pump capacitor 2 connection terminal |
| CP2 | 5 | Charge pump capacitor 2 connection terminal |
| CP3 | 4 | Charge pump capacitor 1 connection terminal |
| CP4 | 3 | Charge pump capacitor 1 connection terminal (GND) |
| CPOUT | 1 | Charge pump output and internal power source. |
| DSG | 8 | Discharge FET gate drive |
| EEPROM | 24 | Active-high EEPROM write-enable pin. During normal operation, should be connected to GND |
| GND | 21, 30, 37 | Power-supply ground |
| GPOD | 44 | General-purpose N-CH FET open-drain output |
| GND | 41 | Should be connected to GND |
| IOUT | 29 | Amplifier output for charge/discharge current measurement |

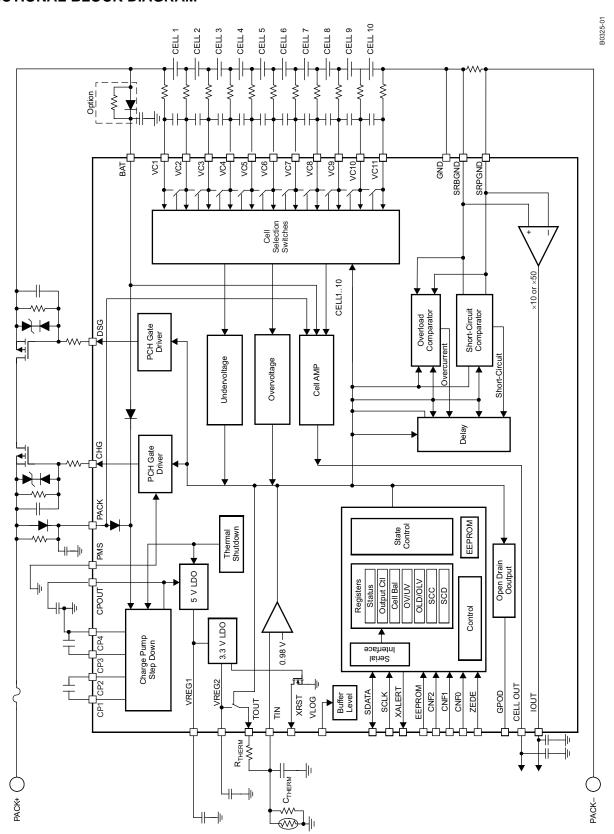


TERMINAL FUNCTIONS (continued)

| NAME | PIN# | DESCRIPTION |
|--------|-----------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NC | 2, 7, 43, 45 | No connect (not electrically connected) |
| PACK | 47 | PACK positive terminal and alternative power source |
| PMS | 46 | Determines CHG output state for zero-volt charge |
| SCLK | 27 | Open-drain bidirectional serial interface clock with an internal 10-kΩ pullup to V _{LOG} |
| SDATA | 26 | Open-drain bidirectional serial interface data with an internal 10-kΩ pullup to V _{LOG} |
| SRBGND | 22 | Current sense terminal (Connect Battery to cell's GND) |
| SRPGND | 23 | Current-sense positive terminal when discharging relative to SRNGND, current-sense negative terminal when charging relative to SRGND. (Connect to pack GND) |
| TIN | 38 | Temperature sensing input |
| TOUT | 39 | Thermistor bias current source |
| VC1 | 10 | Sense voltage input terminal for most positive cell, balance current input for most positive cell, and battery stack measurement input |
| VC2 | 11 | Sense voltage input terminal for second-most positive cell, balance current input for second-most positive cell, and return balance current for most positive cell |
| VC3 | 12 | Sense voltage input terminal for third-most positive cell, balance current input for third-most positive cell, and return balance current for second-most positive cell |
| VC4 | 13 | Sense voltage input terminal for fourth-most positive cell, balance current input for fourth-most positive cell, and return balance current for third-most positive cell |
| VC5 | 14 | Sense voltage input terminal for fifth-most positive cell, balance current input for fifth-most positive cell, and return balance current for fourth-most positive cell |
| VC6 | 15 | Sense voltage input terminal for sixth-most positive cell, balance current input for sixth-most positive cell, and return balance current for fifth-most positive cell |
| VC7 | 16 | Sense voltage input terminal for seventh-most positive cell, balance current input for seventh-most positive cell, and return balance current for sixth-most positive cell |
| VC8 | 17 | Sense voltage input terminal for eighth-most positive cell, balance current input for eighth-most positive cell, and return balance current for seventh-most positive cell |
| VC9 | 18 | Sense voltage input terminal for ninth-most positive cell, balance current input for ninth-most positive cell, and return balance current for eighth-most positive cell |
| VC10 | 19 | Sense voltage input terminal for tenth-most positive cell, balance current input for tenth-most positive cell, and return balance current for ninth-most positive cell |
| VC11 | 20 | Sense voltage input terminal for most negative cell, return balance current for least positive cell |
| VLOG | 32 | Data I/O voltage set by connecting either VREG1 or VREG2 |
| VOUT | 31 | Amplifier output for cell voltage measurement |
| VREG1 | 42 | Integrated 5-V regulator output |
| VREG2 | 40 | Integrated 3.3-V regulator output |
| XALERT | 25 | Open-drain output used to indicate status register change. (Includes an internal 100-kΩ pullup to V _{LOG} .) |
| XRST | 28 | Power-on-reset output. Active-low open-drain output with an internal 3-k Ω pullup to V_{LOG} |
| ZEDE | 36 | Protection delay test pin. Minimizes protection delay times when connected to V _{LOG} . Programmed delay times used when pulled to GND, normal operation. |



FUNCTIONAL BLOCK DIAGRAM





4 SAFETY STATE OVERVIEW

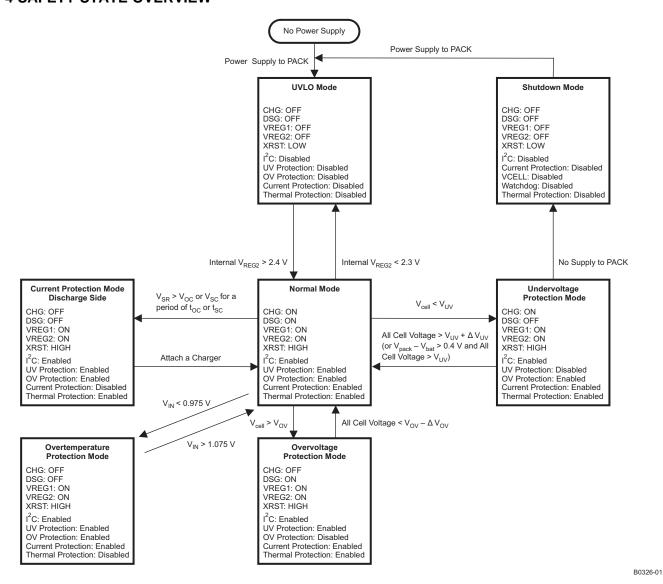


Figure 3. Stand-Alone Mode

Table 1. Stand-Alone STATUS Bit, XALERT and FET Transition Summary

| MODE TRANSITION | STATUS BIT | XALERT | FET ACTIVITY |
|----------------------------------------------------------------------------------------|----------------|--------|-----------------|
| Normal to current protection | SCD or OCD = 1 | H to L | DSG and CHG off |
| Current protection to normal | SCD or OCD = 0 | L to H | DSG and CHG on |
| Normal to overvoltage protection | OVP = 1 | H to L | CHG off |
| Overvoltage protection to normal | OVP = 0 | L to H | CHG on |
| Normal to undervoltage protection (when VPACK goes down to 0 V, move to shutdown mode) | UVP = 1 | H to L | DSG off |
| Undervoltage protection to normal | UVP = 0 | L to H | DSG on |
| Normal to overtemperature | OVT = 1 | H to L | DSG and CHG off |
| Overtemperature to normal | OVT = 0 | L to H | DSG and CHG on |



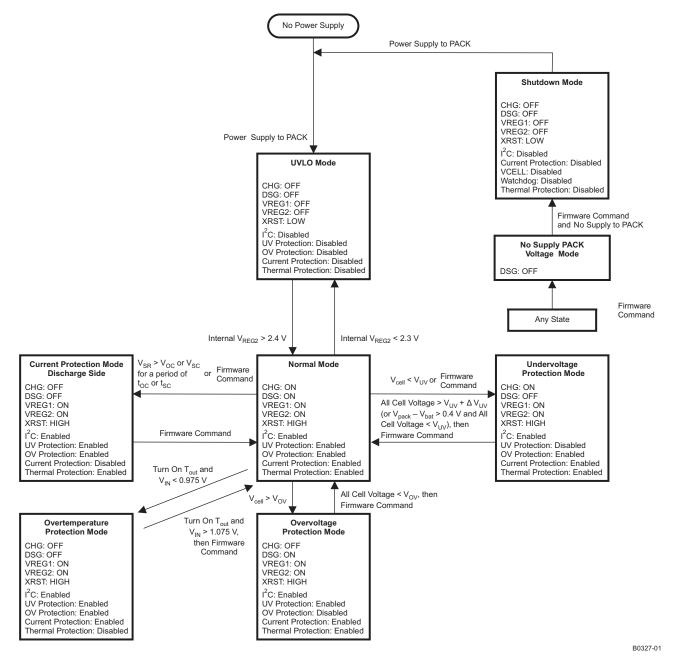


Figure 4. Host-Control Mode



Table 2. Host Control Summary

| MODE TRAN | ISITION | FUNCTION AND FIRMWARE PROCEDURE | | |
|----------------------------------|---------------|-------------------------------------------------------------------------------------------------------------------------------|--|--|
| Normal to current protection | on | Vsr > Voc or Vsc for period of toc or tsc Automatically, DSG and CHG turn off, SCD or OCD status changes = 1, XALERT = L | | |
| Current protection to norm | nal | 1. Send commands to transition LTCLR from 0 to 1 to 0 | | |
| | | 2. Read status bit. XALERT would change to H. | | |
| | | 3. Set CHG and DSG FET ON to enable normal operation | | |
| Normal to overvoltage protection | | Vcell > Vov for period of tov Automatically, CHG turns off, UV status changes = 1, XALERT = L | | |
| Overvoltage protection to | normal | Confirm the OVP protection status is cleared | | |
| | | 2. Send command LTCLR from 1 to 0 | | |
| | | 3. Read status bit. XALERT changes to H. | | |
| | | 4. Set CHG FET ON to enable normal operation | | |
| Normal to undervoltage | UVFET_DIS = 0 | Vcell < Vuv for period of tuv Automatically, DSG turns off, UV status changes = 1, XALERT = L | | |
| protection | UVFET_DIS = 1 | Vcell < Vuv or for period of tuv, UV status changes = 1, XALERT = L | | |
| | | 2. Send commands to turn off DSG. | | |
| Undervoltage protection | | Confirm the OVP protection status is cleared | | |
| to normal | UVFET DIS = X | 2. Send command LTCLR from 1 to 0 | | |
| | UVFEI_DIS = X | 3. Set DSG FET ON to enable normal operation | | |
| | | 4. Read status bit. XALERT changes to H. | | |
| Normal to overtemperatur | е | Send commands to turn on TOUT | | |
| | | 2. If TIN voltage < 0.975 V, DSG and CHG turn off, OVTEMP status changes = 1, XALERT = L | | |
| Overtemperature to norma | al | Send commands to turn on TOUT (To return to normal mode, bq77PL900 must acknowledge Vth > 1.075 V) | | |
| | | 2. Send commands to transition LTCLR from 1 to 0 | | |
| | | 3. Set CHG and DSG FET ON | | |
| | | 4. Read status bit. XALERT changes to H. | | |
| Any mode to shutdown | | 1. Set DSG FET OFF | | |
| | | 2. Wait until PACK voltage decreases to 0 V | | |
| | | 3. SET shutdown bit to 1 | | |

ORDERING INFORMATION

| T _A | PACKAGED SSOP48 |
|----------------|----------------------------|
| -40°C to 100°C | bq77PL900DL ⁽¹⁾ |

(1) The bq77PL900 can be ordered in tape and reel by adding the suffix R to the orderable part number, I.e., bq77PL900DLR.



ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) (1) (2)

| | | | VALUE | UNIT | |
|---------------------|----------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|------|--|
| V _{MAX} | Supply voltage range | BAT, PACK | -0.3 to 60 | V | |
| | | VC1-VC10 | -0.3 to 60 | | |
| | | VC11 | -0.3 to 0.3 | | |
| V | Input voltage range | VCn to VCn + 1, n = 1 to 10 | -0.3 to 8 | V | |
| V _{IN} | input voitage range | PMS | -0.3 to 60 | V | |
| | | SRP, SRN | -0.5 to 1 | | |
| | | SDATA, SCLK, EEPROM, VLOG, ZEDE, CNF0, CNF1, CNF2, TIN | -0.3 to 7 | | |
| | | CHG | PACK – 20 to 60 | | |
| | | DSG | BAT – 20 to 60 | | |
| V | Output voltage range | TOUT, VOUT, IOUT, XRST, XALERT, SDATA, SCLK | -0.3 to 7 | V | |
| Vo | Output voltage range | CP1, CP2, CP3, CP4, CPOUT, GPOD | -0.3 to 60 | V | |
| | | VREG1 | -0.3 to 8 | | |
| | | VREG2 | -0.3 to 3.6 | | |
| I _{CB} | Current for cell balancing | Current for cell balancing | | mA | |
| T _{STG} | Storage temperature ran | nge | -65 to 150 | °C | |
| T _{SOLDER} | Lead temperature (solde | PMS SRP, SRN SDATA, SCLK, EEPROM, VLOG, ZEDE, CNF0, CNF1, CNF2, CHG DSG TOUT, VOUT, IOUT, XRST, XALERT, SDATA, SCLK CP1, CP2, CP3, CP4, CPOUT, GPOD VREG1 VREG2 Int for cell balancing | | °C | |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS

| PACKAGE | T _A ≤ 25°C | DERATING FACTOR | T _A = 85°C | T _A = 100°C |
|---------|-----------------------|-----------------------------|-----------------------|------------------------|
| | POWER RATING | ABOVE T _A ≥ 70°C | POWER RATING | POWER RATING |
| DL | 1388 mW | 11.1 mW/°C | 720 mW | 555 mW |

⁽²⁾ All voltages are with respect to ground of this device except VCn - VC(n+1), where n=1 to 10 cell voltage.

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RECOMMENDED OPERATING CONDITIONS

| | | | | MIN | NOM MAX | UNIT |
|-------------------------------------|--------------------------------|-------------------------------------------|--------------|-------------------------|-------------------------|------|
| Supply Voltag | ge | PACK, BAT | | 7 | 50 | V |
| V _{I(STARTUP)} | | Start-up voltage P | ACK | 7.5 | | V |
| V_{LOG} | Logic supply voltage | | | 0.8 × V _{REG2} | 1.2 × V _{REG1} | V |
| | Input voltage range | VC1 to VC10 | | 0 | BAT | |
| | | VC11 | | 0 | 0.5 | |
| V_{I} | | SRP, SRN | | -0.3 | 0.5 | V |
| | | VCn – VC(n + 1), (n = 1 to 10) PACK, BAT | | 0 | 7 | |
| | | | | | 50 | |
| V _{IH} | Logic level input voltage high | SCLK, SDATA, EI | EPROM, VLOG | 0.8 × V _{LOG} | V_{LOG} | |
| V _{IL} | Logic level input voltage low | (VLOG = VREG1 | or VREG2) | 0 | 0.2 × V _{LOG} | |
| | | XALERT, SDATA | | | V_{LOG} | |
| M | Output valta na nana | VOLIT | VGAIN = High | | 1.2 | V |
| Vo | Output voltage range | VOUT, IOUT | VGAIN = Low | | 0.975 | |
| | | GPOD | | | 45 | V |
| R _{VCX} | | | | | 400 | Ω |
| I _{REGOUT} | | I(reg1 + reg2) | | | 25 | mA |
| C _{REG1} | External 5-V REG capacitor | | | 2.2 | | μF |
| C _{REG2} | External 3.3-V REG capacitor | | | 2.2 | | μF |
| C _{CP1} , C _{CP2} | Charge pump flying capacitor | | | 1 | | μF |
| C _{CPOUT} | Charge pump output capacitor | | | 4.7 | | μF |
| C _{VOUT} | Output capacitance | | | 0.1 | | μF |
| C _{IOUT} | Output capacitance | | | 0.1 | | μF |
| I _{OL} | | GPOD, XRST | | | 1 | mA |
| f _{SCLK} | Input frequency | SCLK | | | 100 | kHz |
| | EEPROM number of writes | | | | 3 | |
| T _{OPR} | Operating temperature | | | -25 | 85 | °C |
| T _{FUNC} | Functional temperature | | | -40 | 100 | °C |



ELECTRICAL CHARACTERISTICS

BAT = PACK = 7 V to 50 V, $T_A = -25$ °C to 85°C, typical values stated where $T_A = 25$ °C and BAT = PACK = 36 V (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | | MIN | TYP | MAX | UNIT |
|--------------------------|-------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------|------|-------|------------|------|
| SUPPLY CUP | RRENT | | | | | | |
| | | No load at REG1, REG2, TOUT, SCLK, SDIN, | T _A = 25°C | | 450 | 550 | |
| I _{CC1} | Supply current 1 | XALERT, CELLAMP, CURRENTAMP = off CHG, DSG = on, cell balance = off, I _{REG1} = I _{REG2} = 0 mA, Charge pump = off ⁽¹⁾ , BAT = PACK = 35 V | T _A = -40°C to 100°C | | | 600 | μΑ |
| I _{CC2} | Supply current 2 | No load at REG1, REG2, TOUT, SCLK, SDIN, XALERT, CELLAMP, CURRENTAMP = on, CHG, DSG = on, Cell balance = off, IREG1 = IREG2 = 0 mA, Charge pump = off, BAT = PACK = 35 V | $T_A = 25$ °C $T_A = -40$ °C to 100 °C | | 650 | 750 800 | μΑ |
| | | OHO DOO " VDEOL VDEOL " | T _A = 25°C | | 0.1 | 1.2 | |
| I _{SHUTDOWN} | Shutdown mode | CHG, DSG = off, VREG1 = VREG2 = off, PACK = 0 V, BAT = 35 V | $T_A = -40$ °C to 100°C | | | 2 | μΑ |
| VREG1, INTE | GRATED 5-V LDO | | · | | | | |
| | 0 1 1 | 8.5 V < PACK or BAT ≤ 50 V, I _{OUT} ≤ 25 mA | $T_A = -40$ °C to | 4.55 | 5 | 5.45 | |
| $V_{(REG1)}$ | Output voltage | 7 V < PACK or BAT ≤ 8.5 V, I _{OUT} ≤ 3 mA | 100°C | 4.55 | 5 | 5.45 | V |
| $\Delta V_{(REG1)}$ | Output temperature drift | PACK or BAT = 50 V, I _{OUT} = 2 mA | T _A = 25°C | | ±0.2% | | 1 |
| ΔV _(REG1LINE) | Line regulation | 10 V ≤ PACK or BAT ≤ 50 V, I _{OUT} = 2 mA | T _A = 25°C | | 10 | 20 | mV |
| , - , | - | PACK or BAT = 36 V, 0.2 mA ≤ I _{OUT} ≤ 2 mA | | | 7 | 15 | |
| $\Delta V_{(REG1LOAD)}$ | Load regulation | PACK or BAT = 36 V, 0.2 mA ≤ I _{OUT} ≤ 25 mA | $T_A = 25^{\circ}C$ | | 40 | 100 | mV |
| | | PACK or BAT = 36 V, VREG1 = 4.5 V | | 35 | 75 | 125 | |
| IREG1MAX | Current limit | PACK or BAT = 36 V, VREG1 = 0 V | $T_A = 25^{\circ}C$ | 5 | 20 | 35 | mA |
| VREG2. INTE | GRATED 3.3-V LDO | | | | | | |
| - , | | 8.5 V < PACK or BAT ≤ 50 V, I _{OUT} ≤ 25 mA | | 3.05 | 3.3 | 3.55 | |
| V _(REG2) | Output voltage | 7 V < PACK or BAT ≤ 8.5 V, I _{OUT} ≤ 10 mA | $T_A = -40$ °C to | 3.05 | 3.3 | 3.55 | V |
| (KEG2) | | 7 V < PACK or BAT ≤ 50 V, I _{OUT} = 0.2 mA | 100°C | -2% | 3.3 | 2% | 1 |
| | Output temperature drift | PACK or BAT = 50 V, I _{OUT} = 2 mA | T _A = -40°C to 100°C | | ±0.2% | | |
| $\Delta V_{(REG2)}$ | Line regulation | 7 V ≤ PACK or BAT ≤ 50 V, I _{OUT} = 2 mA | T _A = 25°C | | 10 | 20 m | mV |
| △ v (REG2) | 0 | PACK or BAT = 36 V, 0.2 mA ≤ I _{OUT} ≤ 2 mA | T _A = 25°C | | 7 | 15 | |
| | Load regulation | PACK or BAT = 36 V, 0.2 mA ≤ I _{OUT} ≤ 25 mA | | | 40 | 100 | mV |
| | | PACK or BAT = 36 V, VREG2 = 3 V | | 25 | 50 | 100 | |
| I _{REG2MAX} | Current limit | PACK or BAT = 36 V, VREG2 = 0 V | T _A = 25°C | 10 | 20 | 30 | mA |
| TOUT, THER | MISTOR POWER SUPPLY | | | | | | |
| V _{TOUT} | | I _{OUT} = 0 mA | $T_A = -40$ °C to 100°C | 3.05 | | 3.55 | V |
| RDS _(ON) | Pass-element series resistance | $I_{OUT} = -1$ mA at TOUT pin, $I_{reg2} = -0.2$ mA RDS _(ON) = $(V_{REG2} - V_{TOUT})/1$ mA | $T_A = -40$ °C to 100°C | | 50 | 100 | Ω |
| V _{TINS} | Thermistor sense voltage | $T_A = -40$ °C to 100°C | | -5% | 0.975 | 5% | > |
| V _{TINSHYS} | Thermistor sense hysteresis voltage | $T_A = -40^{\circ}\text{C to } 100^{\circ}\text{C}$ | | 50 | 100 | 150 | mV |
| THERMAL SH | IUTDOWN | | | | | | |
| T _{therm} | Shutdown threshold | PACK or BAT = 36 V ⁽²⁾ | | | 150 | | °C |
| PMS, PRECH | ARGE MODE SELECT DISA | BLE | | | | | |
| V _{PMSDISABLE} | PMS disable threshold of BAT | PACK = PMS = 20 V, VREG2 = 0 V, CHG = ON - | → OFF | 8 | 13 | 16 | V |
| POR, POWER | R-ON RESET | | | | | | |
| V | Negative-going voltage | VLOG = VREG1(5 V) V | | 3.85 | 4.05 | 4.25 | V |
| V_{POR-} | input | VLOG = VREG2(3.3 V) V | | 2.45 | 2.65 | 2.8 | v |

Charge pump starts working when ($I_{REG33} + I_{REG5}$) > 3 mA. Not 100% tested, assured by design up to 125°C

⁽²⁾



ELECTRICAL CHARACTERISTICS (continued)

BAT = PACK = 7 V to 50 V, $T_A = -25$ °C to 85°C, typical values stated where $T_A = 25$ °C and BAT = PACK = 36 V (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------------------|----------------------------------|--------------------------------------------------------------------------------------------------------------------------------|-------|---------|-------|------|
| V | Desition asian boots as | VLOG = 3.3 V | 50 | 150 | 250 | |
| V_{POR_HYS} | Positive-going hysteresis | VLOG = 5 V | 100 | 250 | 400 | mV |
| t _{RST} | Reset delay time | | 1 | | 5 | ms |
| CELL VOLTA | AGE MONITOR | | | | | |
| | | VCn − VCn + 1 = 0 V , 20 V ≤ BAT ≤ 50 V, VGAIN = Low | 0.925 | 0.975 | 1.025 | |
| V _{CELL OUT} | CELL output | VCn − VCn + 1 = 0 V , 20 V ≤ BAT ≤ 50 V, VGAIN = High | 1.12 | 1.2 | 1.28 | V |
| | | VCn − VCn + 1 = 4.5 V , 20 V ≤ BAT ≤ 50 V | | 0.3 | | |
| REF 1 | CELL output | Mode ⁽³⁾ , 20 V ≤ BAT or PACK ≤ 50 V, VGAIN = Low | -2% | 0.975 | 2% | V |
| REF 2 | CELL output | Mode ⁽⁴⁾ , 20 V ≤ BAT or PACK ≤ 50 V, VGAIN = High | -2% | 1.2 | 2% | V |
| PACK | CELL output | Mode ⁽⁵⁾ | -5% | PACK/50 | 5% | V |
| BAT | CELL output | Mode ⁽⁶⁾ | -5% | BAT/50 | 5% | V |
| CMRR | Common-mode rejection | CELL max to CELL min, 20 V ≤ BAT ≤ 50 V | 40 | | | dB |
| | OFIL soals forter 4 | $ K = \{CELL \ output \ (VC11 = 0 \ V, \ VC10 = 4.5 \ V) - CELL \ output \ (VC11 = VC10 = 0 \ V)\} \ / \ 4.5^{(7)} $ | 0.147 | 0.15 | 0.153 | |
| K1 | CELL scale factor 1 | K = {CELL output (VC2 = 40.5 V , VC1 = 45 V) – CELL output (VC2 = VC1 = 40.5 V)} / $4.5^{(7)}$ | 0.147 | 0.15 | 0.153 | |
| 140 | CELL scale factor 2 | K = {CELL output (VC11 = 0 V, VC10 = 4.5 V) – CELL output (VC11 = VC10 = 0 V)} / $4.5^{(8)}$ | 0.197 | 0.201 | 0.205 | |
| K2 | | K = {CELL output (VC2 = 40.5 V, VC1 = 45 V) – CELL output (VC2 = VC1 = 40.5 V)} / 4.5 ⁽⁸⁾ | 0.197 | 0.201 | 0.205 | |
| I _{VCELLOUT} | Drive current | VCn - VCn + 1= 0 V, Vcell = 0 V, T _A = -40 to 100°C | 12 | 18 | | μΑ |
| V _{ICR} | CELL output offset error | CELL output (VC2 = 45 V, VC1 = 45 V) – CELL output (VC2 = VC1 = 0 V) | | -1 | | mV |
| R _{BAL} | Cell balance internal resistance | RDS _(ON) for internal FET switch at V _{DS} = 2 V, BAT = PACK = 35 V | -50% | 400 | 50% | Ω |
| CURRENT M | IONITOR | | | | | |
| V _{IOUT} | Output voltage | VSRP = VSRN = 0 V (9) | | 1.2 | | V |
| W | lanut offeet voltes a- | VSRP = VSRN = 0 V ⁽⁹⁾ , T _A = 25°C | -3 | | 3 | m)/ |
| V _{OFFSET} | Input offset voltage | VSRP = VSRN = 0 V ⁽⁹⁾ , T _A = -40°C to 100°C | -4 | | 4 | mV |
| | DC gain, low | -100 mV < SRP < 100 mV (10) | -2% | 10 | 2% | |
| | DC gain, high | -20 mV < SRP < 20 mV ⁽¹¹⁾ | -2% | 50 | 2% | |
| I _{IOUT} | Drive current | $V_{IOUT} = 0 \text{ V}, T_A = -40^{\circ}\text{C} \text{ to } 100^{\circ}\text{C}$ | 12 | 18 | | μΑ |

- (3) STATE_CONTROL [VGAIN] = 0, FUNCTION_CONTROL [VAEN] = 1, CELL_SEL[CAL2] = 0, [CAL0] = 1, [CAL0] = 1
 (4) STATE_CONTROL [VGAIN] = 1, FUNCTION_CONTROL [VAEN] = 1, CELL_SEL[CAL2] = 0, [CAL0] = 1, [CAL0] = 1
 (5) STATE_CONTROL [VGAIN] = X, FUNCTION_CONTROL [PACK] = 1, [VAEN] = 1
 (6) STATE_CONTROL [VGAIN] = X, FUNCTION_CONTROL [BAT] = 1, [VAEN] = 1
 (7) STATE_CONTROL [VGAIN] = 0, FUNCTION_CONTROL [VAEN] = 1, CELL_SEL[CAL2] = 0, [CAL0] = 0, [CAL0]
 (8) STATE_CONTROL [VGAIN] = 1, FUNCTION_CONTROL [VAEN] = 1, CELL_SEL[CAL2] = 0, [CAL0] = 0
 (9) STATE_CONTROL [IGAIN] = X, FUNCTION_CONTROL [IAEN] = 1, [IACAL] = 1
 (10) STATE_CONTROL [IGAIN] = 0, FUNCTION_CONTROL [IAEN] = 1, [IACAL] = 0
 (11) STATE_CONTROL [IGAIN] = 1, FUNCTION_CONTROL [IAEN] = 1, [IACAL] = 0



ELECTRICAL CHARACTERISTICS (continued)

BAT = PACK = 7 V to 50 V, $T_A = -25$ °C to 85°C, typical values stated where $T_A = 25$ °C and BAT = PACK = 36 V (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------|----------------------------------------|----------------------------------------|------|-----|------|------|
| BATTERY P | PROTECTION THRESHOLDS | | Ī | | | |
| V _{OV} | OV detection threshold range | Default | 4.15 | | 4.5 | V |
| ΔV_{OV} | OV detection threshold program step | | | 50 | | mV |
| V_{OVH} | OV detection hysteresis voltage range | Default | 0 | | 0.3 | ٧ |
| ΔV_{OVH} | OV detection hysteresis program step | | | 0.1 | | ٧ |
| V _{UV} | UV detection threshold range | Default | 1.4 | | 2.9 | V |
| ΔV_{UV} | UV detection threshold program step | | | 100 | | mV |
| V_{UVH} | UV detection hysteresis voltage | Default | 0.2 | | 1.2 | V |
| ΔV_{UVH} | UV detection threshold program step | | | 200 | | mV |
| V _{OCDT} | OCD detection threshold range | Default | 10 | | 85 | mV |
| ΔV_{OCDT} | OCD detection threshold program step | | | 5 | | mV |
| V _{SCDT} | SCD detection threshold range | Default | 60 | | 135 | mV |
| ΔV _{SCDT} | SCD detection threshold program step | | | 5 | | mV |
| V _{OV_acr} | OV detection threshold accuracy | Default (T _A = 0°C to 85°C) | -50 | 0 | 50 | mV |
| V _{UV_acr} | UV detection threshold accuracy | Default | -100 | 0 | 100 | mV |
| V _{OCD_acr} | OCD detection threshold | V _{OCD} = 10 mV or 15 mV | -4 | 0 | 4 | mV |
| - OCD_acr | accuracy | V _{OCD} > 20 mV | -20% | 0 | 20% | |
| V _{SCD_acr} | SCD detection threshold accuracy | Default | -20% | 0 | 20% | |
| BATTERY P | PROTECTION DELAY TIMES | | Т | | | |
| t _{OV} | OV detection delay time range | Default | 500 | | 2250 | ms |
| Δt_{OV} | OV detection delay time step | | | 250 | | ms |
| t _{UV} | UV detection delay time range | Default | 0 | | 8000 | ms |
| Δt_{UV} | UV detection delay time step | | 1.25 | | 1000 | ms |
| t _{OCD} | OCD detection delay time range | Default | 20 | | 1600 | ms |
| Δt_{OCD} | OCD detection delay time step | | 20 | | 100 | ms |
| t _{SCD} | SCD detection delay time range | Default | 0 | | 900 | μs |
| Δt_{SCD} | SCD detection threshold program step | | | 60 | | μs |
| t _{OV_acr} | OV detection delay time accuracy | Default | -15% | 0% | 15% | |
| t _{UV_acr} | UV detection delay time accuracy | Default | -15% | 0% | 15% | |
| t _{OC_acr} | OC detection delay time accuracy | Default | -15% | 0% | 15% | |
| V _{SCD_acr} | SC detection delay time accuracy | t _{SCD} Max | -15% | 0% | 15% | |
| | | | | | | |



ELECTRICAL CHARACTERISTICS (continued)

BAT = PACK = 7 V to 50 V, $T_A = -25$ °C to 85°C, typical values stated where $T_A = 25$ °C and BAT = PACK = 36 V (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT | |
|-------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------|-------------------------------|------|--------|-----|-------|--|
| t _{SRC} | OC/SC recovery timing in stand-alone mode | | | -15% | 12.8 s | 15% | | |
| BATTERY P | ROTECTION RECOVERY | | | | | | | |
| V _{RECSC} | SC, OC recovery voltage | | | 1 | 1.4 | 2 | V | |
| V _{RECUV} | Undervoltage recover voltage | $V_{RECUV} = V_{PACK-} V_{BAT},$ $V_{UV} + V_{UVH} > V_{CELL} > V_{UV}$ | | 0.05 | 0.1 | 0.3 | ٧ | |
| FET DRIVE | | | | | | | | |
| | Output voltage, charge V _(FETON) and discharge FFTs on V _(FETON) $V(S) = V_{(BAT)} - V_{(DSG)}$, $V(S) = V_{(BAT)} - V_{(BSG)}$ | | | | 12 | 16 | V | |
| V(FETON) | and discharge FETs on | $V_{O(FETONCHG)} = V_{(PACK)} - V_{(CHG)},$ VGS connect 1 M Ω , BAT = PACK = 35 V | | 8 | 12 | 16 | v | |
| V | Output voltage, charge | $V_{O(FETOFFDSG)} = V_{(PACK)} - V_{(DSG)}$, BAT = PAC | K = 35 V | | | 0.2 | V | |
| V _(FETOFF) and discharge | and discharge FETs off | $V_{O(FETOFFCHG)} = V_{(BAT)} - V_{(CHG)}$, BAT = PACH | (= 35 V | | | 0.2 | V | |
| | Rise time | C ₁ = 20 nF. BAT = PACK = 35 V | V _{DSG} : 10% to 90% | | 5 | 15 | | |
| t _r | | | V _{CHG} : 10% to 90% | | 5 | 15 | μѕ | |
| | Fall time | C ₁ = 20 nF, BAT = PACK = 35 V | V _{DSG} : 90% to 10% | | 90 | 140 | | |
| t _f | raii iiiile | CL = 20 11F, BAT = FACK = 35 V | V _{CHG} : 90% to 10% | | 90 | 140 | μs | |
| LOGIC | | | | • | | | | |
| | | XALERT, $I_{OUT} = 200 \mu A$, $T_A = -40 ^{\circ} C$ to $100 ^{\circ}$ | С | | | 0.4 | | |
| V_{OL} | Logic-level output voltage | SDATA, SCLK, XRST, I _{OUT} = 1 mA, T _A = -40°C to 100°C | | | | 0.4 | V | |
| | | GPOD, I _{OUT} = 1 mA, T _A = -40°C to 100°C | | | | 0.6 | | |
| I _{LEAK} | Leakage current | GPOD VOUT = 1 V, T _A = -40°C to 100°C | | | | 1 | μΑ | |
| V _{IH} | SCLK (hysteresis input) | Hysteresis | | | 400 | | mV | |
| | | XALERT, $T_A = -40^{\circ}\text{C}$ to 100°C | | 60 | 100 | 200 | | |
| R_{UP} | Pullup resistance | DATA, SCLK, T _A = -40°C to 100°C | | 6 | 10 | 20 | kΩ | |
| | | XRST, $T_A = -40^{\circ}$ C to 100° C | | 1 | 3 | 6 | ; | |
| I _{DOWN} | Pulldown current | CNF0, CNF1, CNF2 = VREG2 | | | 2 | 4 | μΑ | |



I²C COMPATIBLE INTERFACE

BAT = PACK = 7 V to 50 V, $T_A = -25^{\circ}$ C to 85°C, typical values stated where $T_A = 25^{\circ}$ C and BAT = PACK = 36 V (unless otherwise noted)

| | PARAMETER | MIN | MAX | UNIT |
|-----------------------|----------------------------------------------------------------------|-----|------|------|
| t _r | SCLK, SDATA rise time | | 1000 | ns |
| t _f | SCLK, SDATA fall time | | 300 | ns |
| t _{w(H)} | SCLK pulse duration high | 4 | | μs |
| t _{w(L)} | SCLK pulse duration low | 4.7 | | μs |
| t _{su(STA)} | Setup time for START condition | 4.7 | | μs |
| t _{h(STA)} | START condition hold time after which first clock pulse is generated | 4 | | μs |
| t _{su(DAT)} | Data setup time | 250 | | ns |
| t _{h(DAT)} | Data hold time | 0 | | μs |
| t _{su(STOP)} | Setup time for STOP condition | 4 | | μs |
| t _{su(BUF)} | Time the bus must be free before new transmission can start | 4.7 | | μs |
| t _V | Clock low to data-out valid | | 900 | ns |
| t _{h(CH)} | Data-out hold time after clock low | 0 | | ns |
| f _{SCL} | Clock frequency | 0 | 100 | kHz |

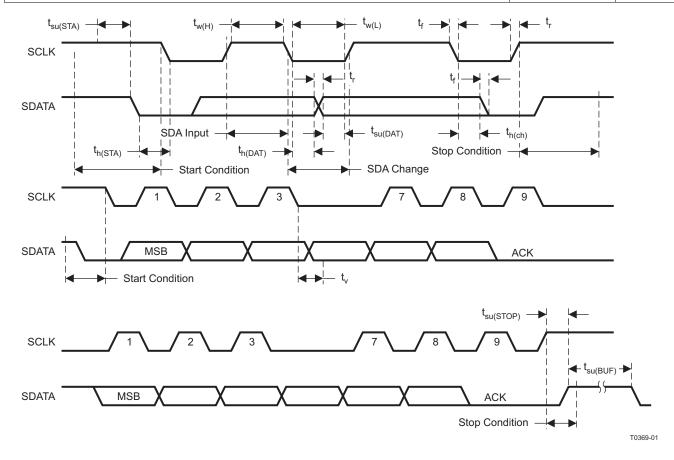


Figure 5. I²C-Like I/F Timing Chart



GENERAL OPERATIONAL OVERVIEW

Stand-Alone Mode and Host Control Mode

The bq77PL900 has two operational modes, stand-alone mode and host-control mode. The mode is switched by STATE_CONTROL [HOST]. In stand-alone mode, the battery protection is managed by the bq77PL900 without the need for any external control. In this mode, the CHG and DSG FETs are driven ON and OFF automatically and cell balancing is processed by a fixed algorithm if enabled by OCDELAY[CBEN]). In this mode, I²C communication is enabled, and a host can read the registers and set STATE_CONTROL [HOST] but cannot control any output or function such as Vcell AMP enable.

In host control mode, a host microcontroller can obtain battery information such as voltage and current from the bq77PL900 analog interface. This allows the host, such as a microcontroller, to calculate remaining capacity or implement an alternative cell balancing algorithm. In this mode, the bq77PL900 still detects cell protection faults and acts appropriately, although the recovery method is different from that in stand-alone mode. The host controller has control over the recovery method and FET action after the protection state has been entered. Table 3 contains further details of the protection action differences.

Table 3. Stand-Alone Mode and Host Control Mode Protection Summary

| FUNCTION | MODE | Stand-Alone Mode (HOST = L) | Host-Control Mode (HOST = H) | | |
|---------------------|------------------------|-------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------|--|--|
| OV protection | Detection | | Automatic The bq77PL900 detects an OV voltage and turns OFF the CHG FET. Must turn off cell balancing for correct voltage detection. | | |
| | Recovery | Automatic The bq77PL900 detects and recovers from | Host Control | | |
| UV protection | Detection | | Host Control The bq77PL900 detects a UV voltage but no FET action is taken. Must turn off cell balancing for correct voltage detection. | | |
| | Recovery | protection states and controls the FETs. | Host Control | | |
| OCD/SCD protection | Detection | | Automatic The bq77PL900 detects OCD and turns CHG and DSG FETs OFF. | | |
| | Recovery | | Host Control | | |
| Overtemperature | Detection | | Host must turn ON. | | |
| protection | Recovery | | Host Control | | |
| CHG/DSG FET control | _ | Automatic Host cannot drive the FETs | Host Control The bq77PL900 cannot release from protection state automatically. | | |
| Cell balancing | _ | CBEN = 1: Automatic CBEN = 0: No function | Host Control The host can balance any cells at any time CBEN = Don't care | | |
| Zero-volt charge1 | PMS = High, ZVC = X | Automatic (0-V charge current flows through CHG FET) | Automatic | | |
| Zero-volt charge2 | PMS = Low, ZVC = 0 | No support for 0-V charge | Host Control | | |
| Zero-volt charge3 | PMS = Low, ZVC = 1 | Automatic (0-V charge current flows through FET that is driven by GPOD) | Host should control precharge FET by using GPOD pin. | | |

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Normal Operation Mode

When all cell voltages are within the range of V_{UV} to V_{OV} , and the CHG and DSG FETs are turned ON, the cells are charged and discharged at any time.

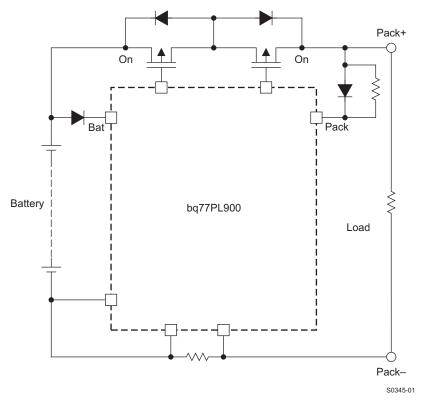


Figure 6. Normal Operation Mode



Battery Protection

The bq77PL900 fully integrates battery protection circuits including cell overvoltage, undervoltage, and overcurrent in discharge and short circuit in discharge detection. Each detection voltage can be adjusted by programming the integrated EEPROM. Also, the detection delay time can be programmed as shown in Table 4.

CAUTION:

Only a maximum of three programming cycles should performed to ensure data stability.

Table 4. Detection Voltage, Detection Delay Time Summary

| PARAMETER | | MIN | MAX | STEP | BITS |
|----------------------------|------------|--------|---------|-----------------|------|
| | Voltage | 4.15 V | 4.5 V | 50 mV | 3 |
| Overvoltage | Delay | 0.5 s | 2.25 s | 0.25 s | 3 |
| | Hysteresis | 100 mV | 400 mV | 50 mV | 2 |
| | Voltage | 1.4 V | 2.9 V | 100 mV | 4 |
| Lladomialtaga | Delay | 0 ms | 30 ms | 1.25 ms-10 ms | 4 |
| Undervoltage | | 1 s | 8 s | 1 s | |
| | Hysteresis | 100 mV | 1200 mV | 0.2 V, 0.4 V | 2 |
| Overeument in disabores | Voltage | 10 mV | 85 mV | 5 mV | 4 |
| Overcurrent in discharge | Delay | 20 ms | 1600 ms | 20 ms or 100 ms | 5 |
| Chart aircuit in diagharas | Voltage | 60 mV | 135 mV | 5 mV | 4 |
| Short circuit in discharge | Delay | 0 μs | 900 μs | 60 μs | 4 |

Cell Overvoltage and Cell Undervoltage Detection

The cell overvoltage and cell undervoltage detection circuit consists of a sample-and-hold (S/H) circuit and two comparators.

The S/H period is about 120 μ s for each cell, and S/H is performed sequentially on each cell. Once all of the cells are checked, the bq77PL900 waits about 50 mS for the next S/H.

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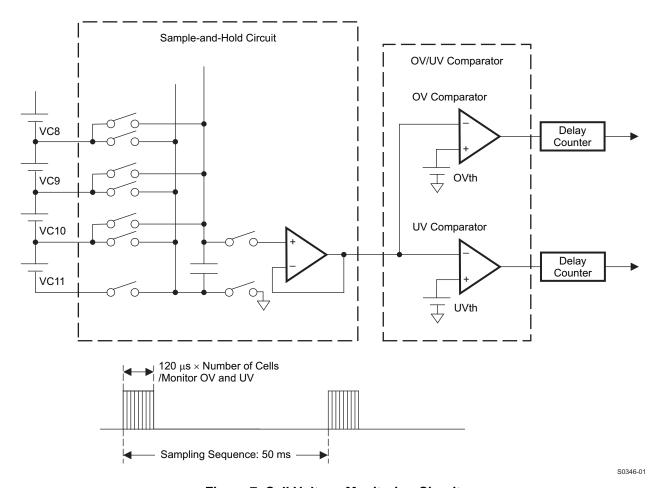


Figure 7. Cell Voltage Monitoring Circuit

Cell Overvoltage Detection and Recovery

Cell overvoltage detection is the same as host control mode for the FET OFF state, but the recovery conditions are different. The CHG FET is turned OFF if any one of the cell voltages remains higher than V_{OV} for a period greater than t_{OV} . As a result, the cells are protected from an overcharge condition. Also XLAERT changes from High to Low. Both V_{OV} and t_{OV} can be programmed in the internal EEPROM.

Recovery in Host Control Mode

The recovery condition is as follows:

- 1. All cell voltages become lower than V_{OV} (ΔV_{OVH} is ignored).
- Additionally, the host must send a sequence of firmware commands to the bq77PL900 to turn ON the CHG FET.

The command sequence required is as follows:

- 1. The host must toggle LTCLR from 0 to 1 and then back to 0.
- 2. Then set the CHG control bit to 1. To reset XLAERT high, the host must read the status register.

Figure 8 illustrates the circuit schematic in overvoltage protection mode in Host Control Mode. Figure 9 illustrates the timing of this protection mode.



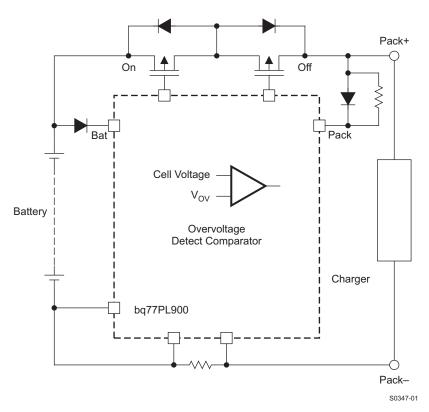


Figure 8. Overvoltage in Host-Control Mode



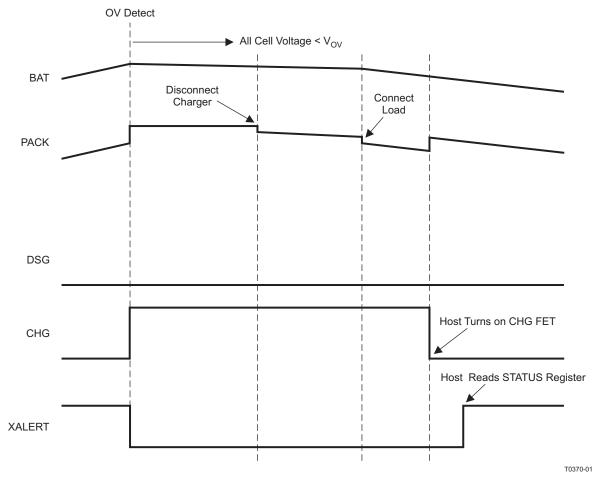


Figure 9. OV and OV Recovery Timing in Host-Control Mode



Recovery in Stand-Alone Mode

The recovery condition occurs when all cell voltages become lower than $(V_{OV} - \Delta V_{OVH})$.

Figure 10 illustrates the circuit schematic in overvoltage protection mode in stand-alone mode. Figure 11 illustrates the timing of this protection mode.

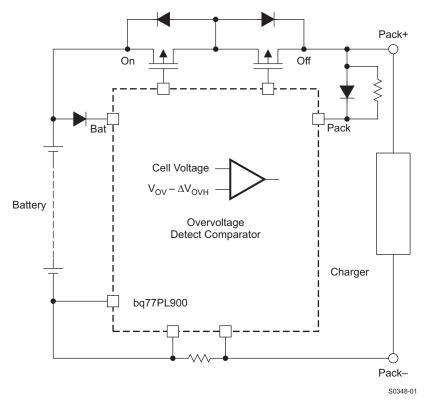


Figure 10. Cell Overvoltage Protection Mode in Stand-Alone Mode



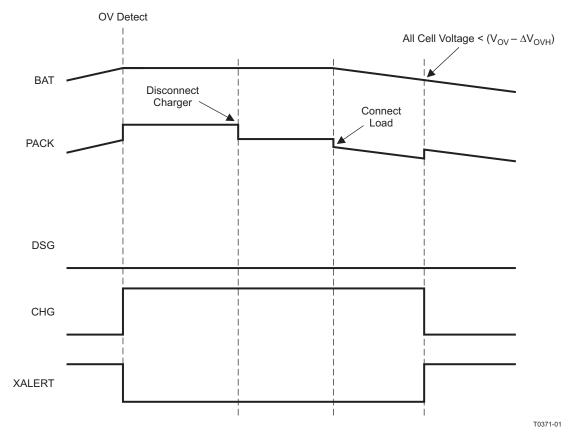


Figure 11. OV and OV Recovery Timing in Stand-Alone Mode



7.14.1 Cell Undervoltage Detection and Recovery

When any one of the cell voltages falls below V_{UV} for a period of t_{UV} , the bq77PL900 enters the undervoltage mode. At this time, the DSG FET is turned OFF and XALERT driven low. Both V_{UV} and t_{UV} can be programmed in the internal EEPROM.

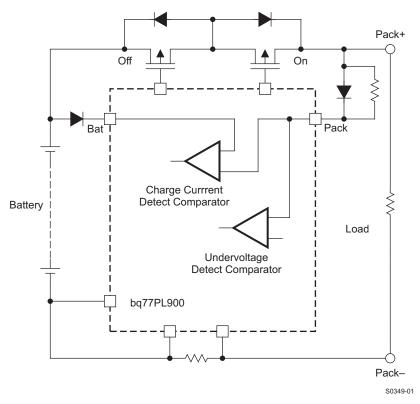


Figure 12. Cell Undervoltage Protection Mode in Host Mode and Stand-Alone Mode (Attaching a Charger)

In Host-Control Mode

Cell undervoltage protection recovery conditions are when:

- 1. All cell voltages become higher than $(V_{UV} + \Delta V_{UVH})$, or
- 2. All cell voltages are higher than V_{UV} AND a charger is connected between PACK+ and PACK-, noting that PACK+ voltage must be higher than BAT due to the diode forward voltage.

The bq77PL900 monitors the voltage difference between the PACK+ and BAT pins. When a difference higher than 0.4V (typ.) is seen, it is interpreted that a charger has been connected.

Figure 12 illustrates the circuit schematic in undervoltage protection mode.

In some applications, it is required not to turn OFF the DSG FET suddenly. In these cases, by setting **UVLEVLE [UVFET_DIS]** = 1, only XALERT is driven low in response to entering an undervoltage condition. The host can turn OFF the DSG FET to protect the undervoltage condition. When the bq77PL900 recovery condition is satisfied, the host must send a sequence of firmware commands to the bq77PL900. The firmware command sequence to turn ON the DSG FET is as follows:

- 1. The host must toggle LTCLR from 0 to 1 and back to 0.
- 2. Then the host must set the DSG ON bit to 1.
- 3. Then the host can read the status register to reset XALERT high.

Figure 13 and Figure 14 illustrate the timing chart of protection mode.



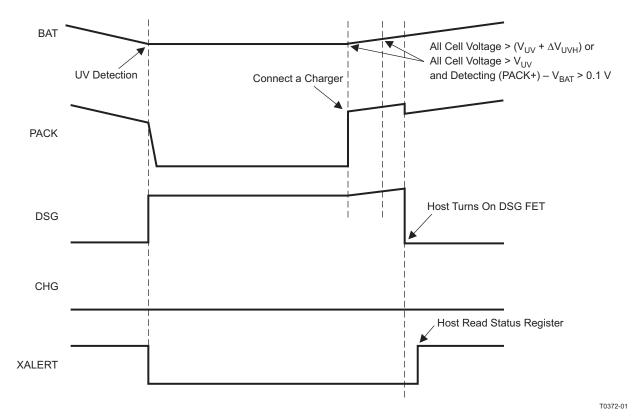


Figure 13. UV and UV Recovery Timing Host-Control Mode (UVFET_DIS = 0)

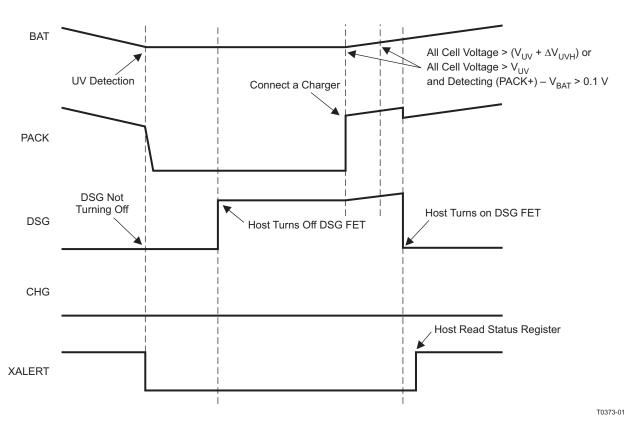


Figure 14. UV and UV Recovery Timing Host Control Mode (UVFET_DIS = 1)

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In Stand-Alone Mode

On detecting entry to undervoltage mode, the bq77PL900 moves to the *shutdown* power mode.

When a charger is attached, the bq77PL900 wakes up from shutdown mode. If cell voltages are lower than the undervoltage condition, the DSG FET is turned OFF and XALERT driven low. During periods when a charger is attached, the bq77PL900 never changes to shutdown mode.

When the undervoltage recovery condition is satisfied, the DSG FET turns ON and XLAERT is reset high.

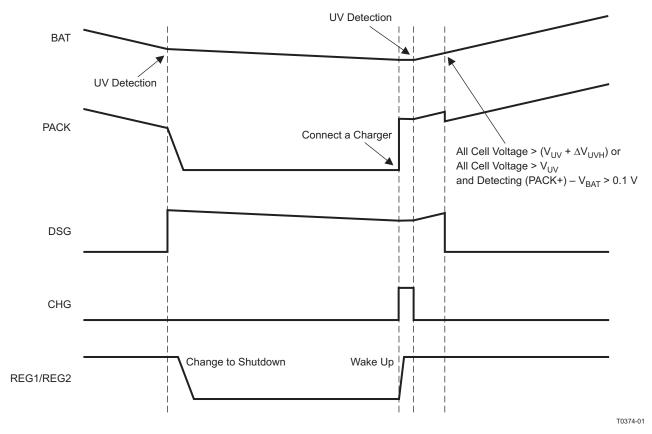


Figure 15. UV and UV Recovery in Stand-Alone Mode

Overcurrent in Discharge (OCD) Detection

The overcurrent in discharge detection feature detects abnormal currents in the discharge direction via measuring the voltage across the sense resistor (V_{OCD}) and is used to protect the pass FETs, cells, and any other inline components from abnormal discharge current conditions. The detection circuit also incorporates a blanking delay period (t_{OCD}) before turning OFF the pass FETs. Both V_{OCD} and t_{OCD} can be programmed in internal EEPROM.

Short Circuit in Discharge (SCD) Detection

The short circuit in discharge detection feature detects severe discharge current via measuring the voltage across the sense resistor (V_{SCD}) and is used to protect the pass FETs, cells, and any other inline components from severe current conditions. The detection circuit also incorporates a blanking delay period (t_{SCD}) before turning OFF the pass FETs. Both V_{SCD} and t_{SCD} can be programmed in the internal EEPROM.

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7.14.1 Overcurrent in Discharge and Short Circuit in Discharge Recovery

In host-control mode, the host must send a sequence of firmware commands to the bq77PL900 to recover from overcurrent and short-circuit currents. The command sequence to turn ON the DSG and CHG FETs is as follows:

- 1. The host must toggle LTCLR from 0 to 1 and back to 0.
- 2. Then set the DSG and CHG control bits to 1. To reset XALERT high, the STATUS register must be read.

In stand-alone mode, the bq77PL900 has two methods to recover from overcurrent and short-circuit conditions by setting the SOR bit of OCD_CFG.

SOR = 0: Recover comparator is active after 12.8 s. An internal comparator monitors the PACK+ voltage and when the PACK+ voltage reaches V_{RECSC} , the overcurrent in discharge recovers. When the bq77PL900 detects a charger is attached, the DSG and CHG FETs turn ON and XALERT is reset High.

SOR = 1: After 12.8 s, the bq77PL900 automatically recovers from OC and SC. The DSG and CHG FETs turn ON and XALERT is reset high. If the OC or SC condition is still present, OC and SC is detected again and the recovery/detection cycle continues until the fault is removed.

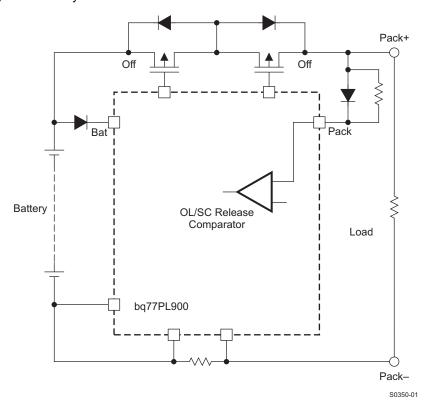


Figure 16. Overcurrent and Short-Circuit Protection Modes



Table 5. Detection and Recovery Condition Summary (Stand-Alone Mode)

| | | | | - |
|----------------------|-----------------------------------------------------------|------------------------------------------------------------------|----------------------------------------------------------------------|----------------------------------------------------------------------|
| | CELL OVERVOLTAGE | CELL UNDERVOLTAGE | OVERCURRENT IN DISCHARGE | SHORT CIRCUIT IN DISCHARGE |
| Detection condition | Any cell voltage > V _{OV} | Any cell voltage < V _{UV} | $(V_{SRP} - V_{SRN}) > V_{OCD}$ | $(V_{SRP} - V_{SRN}) > V_{SCD}$ |
| CHG FET | $ON \to OFF$ | ON | $ON \to OFF$ | $ON \to OFF$ |
| DSG FET | ON | $ON \to OFF$ | $ON \to OFF$ | $ON \to OFF$ |
| Recovery condition 1 | All cell voltage < (V _{OV} – ΔV _{OVH}) | All cell voltages > (V _{UV} + ΔV _{UVH}) | SOR = 0: Attach a charger SOR = 1: OC condition is released | SOR = 0: Attach a charger SOR = 1: SC condition is released |
| Recovery condition 2 | | All cell voltages > V_{UV} AND PACK+ - V_{BAT} > 0.1 V | | |
| CHG FET | $OFF \to ON$ | ON | $OFF \to ON$ | $OFF \to ON$ |
| DSG FET | ON | $OFF \to ON$ | $OFF \to ON$ | $OFF \to ON$ |

Table 6. Detection and Recovery Condition Summary (Host-Control Mode)

| | CELL OVERVOLTAGE | CELL UNDERVOLTAGE | OVERCURRENT IN DISCHARGE | SHORT CIRCUIT IN DISCHARGE |
|------------------------|------------------------------------------------------------|-------------------------------------------------------------------|---------------------------------|---------------------------------|
| Detection condition | Any cell voltage > V _{OV} | Any cell voltage < V _{UV} | $(V_{SRP} - V_{SRN}) > V_{OCD}$ | $(V_{SRP} - V_{SRN}) > V_{SCD}$ |
| CHG FET | $ON \to OFF$ | ON | $ON \to OFF$ | $ON \to OFF$ |
| DSG FET | ON | ON → OFF (UVFET_DIS = 0) | $ON \to OFF$ | $ON \to OFF$ |
| Recovery condition 1 | All cell voltage < V _{OV} (ignore the hysteresis) | All cell voltage > $(V_{UV} + \Delta V_{UVH})$ | None | None |
| Recovery condition 2 | | All cell voltage > V _{UV} AND VPACK - VBAT > 0.1 V | | |
| CHG FET ⁽¹⁾ | $OFF \to ON$ | ON | $OFF \to ON$ | $OFF \to ON$ |
| DSG FET ⁽¹⁾ | ON | $OFF \to ON$ | $OFF \to ON$ | $OFF \to ON$ |

⁽¹⁾ Host is required to set and clear LTCLR, then turn on the FETs.

Low-Dropout Regulators (REG1 and REG2)

The bq77PL900 has two low dropout (LDO) regulators that provide power to both internal and external circuitry. The inputs for these regulators can be derived from the PACK or BAT terminals (see the Initialization section for further details). The output of REG1 is typically 5 V, with a minimum output capacitance of 2.2 μ F required for stable operation. It is also internally current-limited. During normal operation, the regulator limits the output current, typically to 25 mA. The output of REG2 is typically 3.3 V, also with a minimum output capacitance of 2.2 μ F for stable operation, and it is also internally current-limited.

Until the internal regulator circuit is correctly powered, the DSG and CHG FETs are driven OFF.

Initialization

From a shutdown situation, the bq77PL900 requires a voltage greater that the start-up voltage (V_{STARTUP}) applied to the PACK pin to enable its integrated regulator and provide the regulator power source. Once the REG1 and REG2 outputs become stable, the power source of the regulator is switched to BAT.

After the regulators have started, they then continue to operate through the BAT input. If the BAT input is below the minimum operating range, then the bq77PL900 does not operate until the supply to the PACK input is applied.

If the voltage at REG2 falls, the internal circuit turns off the CHG and DSG FETs and disables all controllable functions, including the REG1, REG2, and TOUT outputs.

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Series Configuration of Five to Ten Cells

Unused cell inputs are required to be shorted to the uppermost-voltage-connected terminal. For example, in a five-cell configuration, VC1 to VC5 are shorted to VC6. In a 9-cell configuration, VC1 is shorted to VC2.

The CNF0, CNF1, and CNF2 pins should be connected to VLOG = logic 1 (through a10-k Ω resistance) or GND = logic 0 (directly) according to the desired cell configuration as seen in Table 7.

CELL CNF1 PIN CNF0 PIN CNF2 PIN CONFIGURATION 0 Λ Λ 10-cell 0 0 1 9-cell 0 1 0 8-cell 0 1 1 7-cell 1 0 6-cell 0 0 1 1 5-cell 10-cell All other combinations

Table 7. Cell Configuration

Delay Time Zero

The ZEDE pin enables EEPROM-programmed detection delay times when connected with GND (normal operation). The detection delay time is set to 0 when this pin is connected with VLOG. This is typically used in battery manufacturing test only.

Cell Voltage Measurement

The cell voltage is translated to allow a host controller to measure individual series elements of the battery. The series element voltage is presented on the VOUT terminal. The cell voltage amplifier gain can be selected as one of the following two equations. The VOUT voltage gain is selected by STATE_CONTROL [VGAIN]. VOUT is internally connected to ground when disabled.

 $V_{OUT}1 = 0.975 - \{(Cell \ voltage) \times 0.15\}$ when VGAIN = 0 or

 V_{OUT} 2 = 1.2 – {(Cell voltage) × 0.20} when VGAIN = 1

The total pack voltage can also be monitored. The PACK voltage output is enabled or disabled by FUNCTION_CONTROL [PACK].

 $V_{OUT}3 = (Total pack voltage) \times 0.02$ when PACK = 1

The total pack voltage can also be monitored. The BAT voltage output is enabled or disabled by FUNCTION_CONTROL [BAT].

 $V_{OUT}4 = (Total battery voltage) \times 0.02 when BAT = 1$

Cell Voltage Measurement Calibration

The bq77PL900 cell-voltage monitor consists of a sample-and-hold (S/H) circuit and differential amplifier.



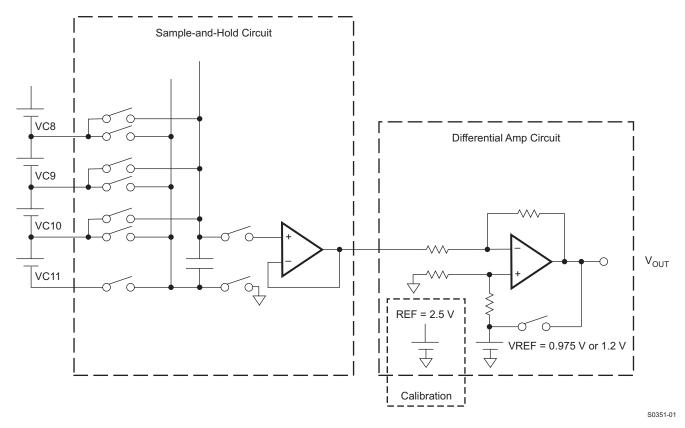


Figure 17. Cell Voltage Monitoring Circuit

To calibrate the VCELL output, it must measure a 2.5-V signal, but 2.5 V is beyond the ADC input range of most analog-to-digital converters used in these applications. The bq77PL900 is designed to measure the 2.5 V through a differential amplifier first, which is where the calibration procedure starts.

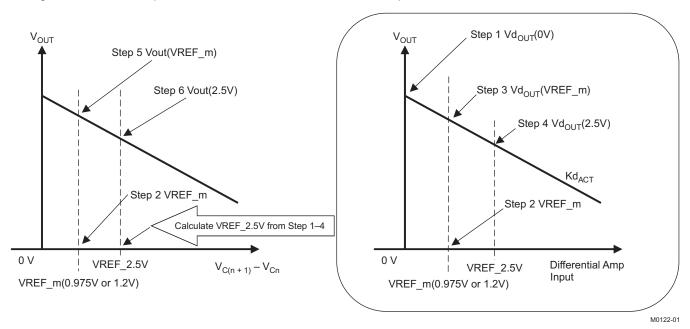


Figure 18. Calibration Method

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Step 1

Measure the output voltage of the differential amplifier at 0-V input (both inputs of the differential amplifier are connected to GND). The output voltage includes the offset and is represented by:

 $Vd_{OUT}(0V)$ = measured output voltage of differential amplifier at 0-V input (This value includes an offset voltage (V_{OS}) and a reference voltage.)

Step 2

Set CAL2 = 0, CAL1 = 1, CAL0 = 1, VAEN = 1

VREF is trimmed to 0.975 V or 1.2 V within ±2%. Then measure internal reference voltage VREF directly from VOUT:

VREF_m = measured reference voltage (0.975 V or 1.2 V)

Step 3

Measure the scaled REF voltage through the differential amplifier.

Vd_{OUT}(VREF_m) = The output voltage, including the scale factor error and offset

$$= VREF + (1 + K) \times VOS - K \times VREF$$

=
$$VREF_m + (1 + Kd_{ACT}) \times V_{OS} - Kd_{ACT} \times VREF_m$$

where:
$$VREF_m + (1 + Kd_{ACT}) \times V_{OS} = Vd_{OUT}(0V)$$

$$Kd_{ACT} = (Vd_{OUT}(0V) - Vd_{OUT}(VREF_m)) / VREF_m$$

= (measured value at step 1 - measured value at step 3)/ measured value at step 2

Calibrated differential voltage is calculated by:

$$Vdout = VREF + (1 + K) \times V_{OS} - K \times Vdin$$

$$= Vd_{OUT}(0V) - Kd_{ACT} \times Vdin$$

Where: Vdin = input voltage of differential amp lifier

Step 4

Measure scaled REF(2.5V) though differential amp,

Some TI-Benchmarq gas gauges cannot measure 2.5 V directly, because the ADC input voltage is 1 V. So to measure the 2.5-V internal reference voltage, use a differential amplifier as a method to scale down the measurement value.

Vdout(2.5V) = measured differential amp output voltage at the 2.5-V input

Already, differential amplifier calibration was performed in steps 1, 2, and 3.

So VREF_2.5V is presented by

$$VREF_2.5V = \{ Vd_{OUT}(0V) - Vdout(2.5V) \}/Kd_{ACT}$$

Step 5

Vout(0.975V or 1.2V) = Measure scaled REF (0.975-V or 1.2-V) output voltage S/H and differential amplifier.

Step 6

Vout(2.5V) = Measure scaled REF (2.5-V) output voltage S/H and differential amp.

Scale factor

$$K_{ACT} = -(V_{OUT}(2.5V) - V_{OUT}(0.975V \text{ or } 1.2V)/(VREF_2.5V - VREF_m)$$

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$$\label{eq:Vout} \begin{split} &\text{Vout}(0\text{V}) = \text{V}_{\text{OUT}}(2.5\text{V}) + \text{K}_{\text{ACT}} \times \text{VREF}_2.5\text{V} \\ &\text{OR} \\ &\text{Vout}(0\text{V}) = \text{V}_{\text{OUT}}(0.975\text{V or } 1.2\text{V}) + \text{K}_{\text{ACT}} \times \text{VREF}_m \\ &\text{Cell voltage is calculated by as follows:} \\ &\text{VCn} - \text{VC}(\text{n} + 1) = \{\text{Vout}(0\text{V}) - \text{V}_{\text{OUT}}\} \, / \, \text{K}_{\text{ACT}} \end{split}$$

Current Monitor

Discharge and charge currents are translated to allow a host controller to measure accurately current, which measurement can then be used for additional safety features or calculating the remaining capacity of the battery. The sense resistor voltage is converted using the following equation. The typical offset voltage is V_{CELL_OFF} (1.2 V typical), although it can be presented on the IOUT pin for measurement, if required.

The output voltage increases when current is positive (discharging) and decreases when current is negative (charging).

$$V_{CURR} = 1.2 + (I_{PACK} \times R_{SENSE}) \times (IGAIN)$$

where

State_Control [IGAIN] = 1 then IGAIN = 50 State_Control [IGAIN] = 0 then IGAIN = 10

The current monitor amplifier can present the offset voltage as shown in Table 8. The IOUT pin is enabled or disabled by *FUNCTION_CONTROL [IACAL, IAEN]* and has a default state of OFF. IOUT is internally connected to ground when disabled.

| rabio of interfer and interfer configuration | | | | | |
|----------------------------------------------|-------|------|-----------|--|--|
| | IACAL | IAEN | CONDITION | | |
| | 0 | 1 | NORMAL | | |
| | 1 | 1 | OFFSET | | |
| | Χ | 0 | OFF | | |

Table 8. IACAL and IAEN Configuration

Cell Balance Control

The integrated cell balance FETs allow a bypass path to be enabled for any one series element. The purpose of this bypass path is to reduce the current into any one cell during charging to bring the series elements to the same voltage. Series resistors placed between the input pins and the positive series element nodes limits the bypass current value. Series input resistors between 500 Ω and 1 k Ω are recommended for effective cell balancing.

In host-control mode, individual series element selection is made via CELL_BALANCE [CBAL1, CBAL2, CBAL3, CBAL4, CBAL5, CBAL6, CBAL7, and CBAL8] and FUNCTION_CONTROL [CBAL9, CBAL10].

In stand-alone mode, cell balancing works as shown in Figure 19. When a certain cell (cell A) voltage reaches cell overvoltage, the battery charging stops and then cell balance starts working at ta. The cell-A voltage decreases by the bypass current until the voltage reaches ($V_{OV} - \Delta V_{OVH}$). Cell-B voltage does not change during the period because cell balancing works only for the cell that reached V_{OV} . At tb, battery charging starts again. Cell A and cell B have been charged in this period until cell-A voltage reaches V_{OV} again. The voltage difference between cell A and cell B becomes smaller when the bq77PL900 repeats the foregoing cycle. The bq77PL900 stops cell balance when cell overvoltage protection has released.

The bq77PL900 is designed to prevent cell balancing on adjacent cells or on every other cell. For example, if cell overvoltage happened to cell 8, cell 7 (cell 7 is next to cell 8) and cell 3 (cell 3 is **not** next to cell 8 or cell 7), then cell balancing starts for cell 8 and cell 3 first. When the cell-8 voltage is back to normal, then cell balancing starts for cell 7.

While the bq77PL900 monitors the overvoltage and undervoltage, cell balancing is automatically turned off. This configuration is supported for both modes (host-control and stand-alone modes).



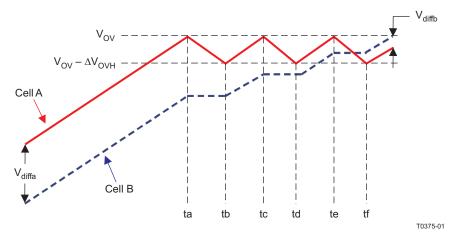


Figure 19. Cell Balancing Timing Chart (Automatic)

Thermistor Drive Circuit (TOUT), Thermistor Input (TIN)

The TOUT pin is powered by REG2, can be enabled via *FUNCTION_CONTROL [TOUT]* to drive an external thermistor, and is OFF by default. A 10-k Ω , 25°C NTC (e.g., Semitec 103AT) thermistor is typical. The maximum output impedance is 100 Ω .

The bq77PL900 monitors the battery temperature as shown in Figure 20. A voltage divided by the NTC thermistor and reference resistor is connected to TIN. The bq77PL900 compares the TIN voltage with the internal reference voltage (0.975V), and when $V_{TIN} < V_{REF}$ the bq77PL900 turns OFF the CHG and DSG FETs and sets STATUS [OVTEMP].

In host-control mode, the host should enable and disable TOUT.

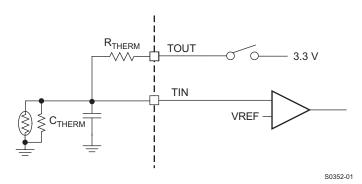


Figure 20. Temperature Monitoring Circuit

General-Purpose Open-Drain Drive (GPOD)

The GPOD output is enabled or disabled by OUTPUT CONTROL [GPOD] and has a default state of OFF.

In stand-alone mode, this pin is used for driving the 0-V/precharge FET for zero-voltage battery charging by OCD_CFG [ZVC] = 1.

Alerting the Host (XALERT)

In both modes, the XALERT pin is available and is driven low when faults are detected. The method to clear the XALERT pin is different in stand-alone mode than in host-control mode. In stand-alone mode, XLAERT is cleared when all of the faults are cleared. In host-control mode, the host must toggle (from 0, set to 1, then reset to 0) OUTPUT_CONTROL [LTCLR] and then read the STATUS register.



Alerting the Host (LTCLR)

In host-control mode, when a protection fault occurs, the state is latched. The fault flag is unlatched by toggling (from 0, set to 1 then reset to 0) *OUTPUT_CONTROL [LTCLR]*. The OCD, SCD, OV, and UV bits are unlatched by this function. Now the FETs can be controlled by programming the *OUTPUT_CONTROL* register, and the XALERT output can be cleared by reading the *STATUS* register. When detecting overvoltage or undervoltage faults, LTCTR changes are ignored. After a period of 1 ms, it must send an LTCLR command.

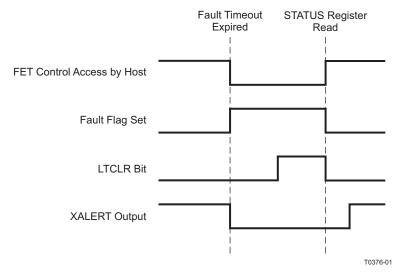


Figure 21. LTCLR and XLAERT Clear Timing (Host-Control Mode)

POR

The XRST open-drain output pin is triggered on activation of the VREG1 or VREG2 output. This holds the host controller in reset for t_{RST} , allowing V_{VREG2} to stabilize before the host controller is released from reset.

The XRST output and monitoring voltage is supplied by the source of VLOG. When VLOG is connected to VREG1, the XRST output level is V_{VREG1} and monitors the activation of VREG1. When VLOG is connected to VREG2, the XRST output level is V_{VREG2} and monitors the activation of VREG2.

When V_{VREG1} or V_{VREG2} voltage is below the output specifications, XRST is active-low (0.8 × VLOG). When V_{BAT} is below 7 V, VREG1 and VREG2 stop, then XRST goes low. If a host has a problem with a sudden reset signal, it is recommended monitoring the battery voltage to avoid it, e.g., burnout detection.

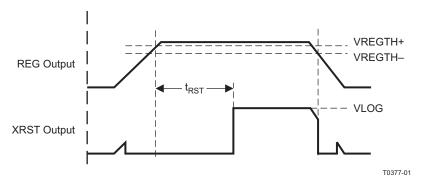


Figure 22. XRST Timing Chart - Power Up and Power Down



EEPROM Write Sequence

The bq77PL900 has integrated configuration EEPROM for OV, UV, OCD, and SCD thresholds and delays. The appropriate configuration data is programmed to the configuration registers, and then 0xe2 is sent to the EEPROM register to enable the programming supply voltage. By driving the EEPROM pin (set high and then low), the data is written to the EEPROM.

When supplying BAT, care should be taken not to exceed VCn - VC(n + 1), (n = 1 to 10) > 5 V. If BAT and VC1 are connected onboard, it is recommended that all cell-balance FETs be ON where each input voltage is divided with the internal cell-balance ON resistance.

The recommended voltage at BAT or PACK for EEPROM writing is 20 V. When supplying VBAT, care is needed to ensure VBAT does not exceed the VCn - VC(n + 1), (n = 1 to 10) absolute maximum voltage. If BAT and VC1 are connected onboard, supplying 7.5 V is recommended to activate the bq77PL900 and turn ON all cell-balance FETs.

Then increase the power supply up to 20 V. By this method, each input voltage is divided with the internal cell-balance ON resistance.



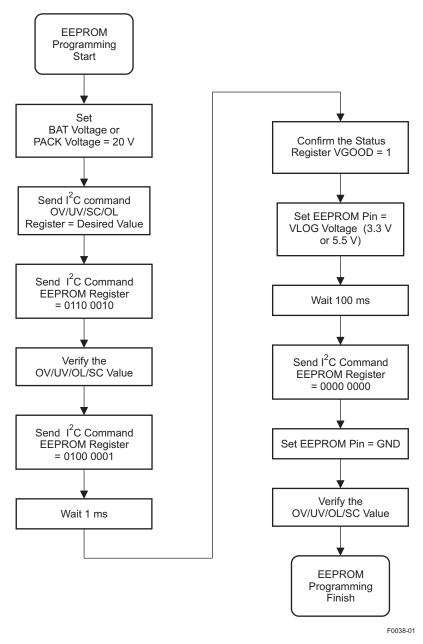


Figure 23. EEPROM Data-Writing Flow Chart



Power Modes

The bq77PL900 has two power modes, normal and shutdown. Table 9 outlines the operational functions during the two power modes.

Table 9. Power Modes

| POWER MODE | TO ENTER NORMAL MODE | MODE DESCRIPTION |
|---------------|---------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Normal | | The battery is in normal operation with protection, power management, and battery monitoring functions available and operating. The supply current of this mode varies, as the host can enable and disable various features. |
| Shutdown | Add supply at the V _{PACK} < V _{WAKE} | When undervoltage is detected in stand-alone mode, or shutdown command at host-control mode, the bq77PL900 goes into shutdown: all outputs and interfaces are OFF and memory is not valid. |

Shutdown Mode

In host-control mode, the bq77PL900 enters shutdown mode when it receives the shutdown command, STATE_CONTROL [SHDN] set. First, the DSG FET is turned OFF, and then after the pack voltage goes to 0 V, the bq77PL900 enters shutdown mode, which stops all functions of the bq77PL900.

In stand-alone mode the bq77PL900 enters shutdown when the battery voltage falls and UV is detected. It turns the DSG FET OFF, and after the pack voltage goes to 0 V, the bq77PL900 enters shutdown mode, which stops all functions.

Exit From Shutdown

If a voltage greater than $V_{STARTUP}$ is applied to the PACK pin, then the bq77PL900 exits from shutdown and enters normal mode.

Parity Check

The bq77PL900 uses EEPROM for storage of protection thresholds, delay times, etc. The EEPROM is also used to store internal trimming data. For safety reasons, the bq77PL900 uses a column parity error checking scheme. If the column parity bit is changed from the written value, then $OUT_CONTROL\ [PFALT]$ is set to 1 and XALERT driven low. In stand-alone mode, both DSG and CHG outputs are driven high, turning OFF the DSG and CHG FETs. The GPOD output is also turned off.

In host-control mode, only *OUT_CONTROL* [*PFALT*] and the XALERT output are changed, allowing the microprocessor host to control bq77PL900 operation.

Communications

The I²C-like communication provides read and write access to the bq77PL900 data area. The data is clocked via separate data (SDATA) and clock (SCLK) pins. The bq77PL900 acts as a slave device and does not generate clock pulses. Communication to the bq77PL900 can be provided from the GPIO pins of a host controller. The slave address for the bq77PL900 is 7 bits and the value is 0010 000.

| | (MSB) | | I ² C Address + R/W Bit | | | | | | | |
|-------|-------|---|------------------------------------|---|---|---|---|---|--|--|
| | (MSB) | | | | | | | | | |
| Write | 0 | 0 | 4 | 0 | 0 | 0 | 0 | 0 | | |
| Read | U | U | ı | U | U | U | U | 1 | | |

The bq77PL900 does NOT have the following functions compatible with the I²C specification.

- The bq77PL900 is always regarded as a slave.
- The bq77PL900 does not support the general code of the I²C specification and therefore does not return an ACK, but may return a NACK.
- The bq77PL900 does not support the address auto-increment, which allows continuous reading and writing.
- The bq77PL900 allows data to be written to or read from the same location without resending the location address.

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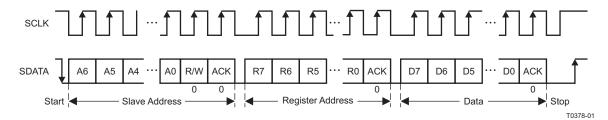


Figure 24. I²C-Bus Write to bq77PL900

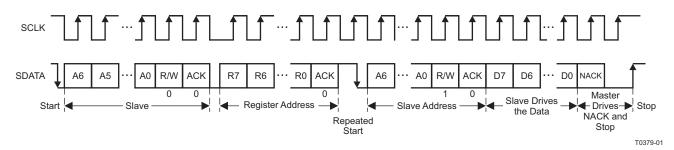


Figure 25. I²C-Bus Read From bq77PL900: Protocol A

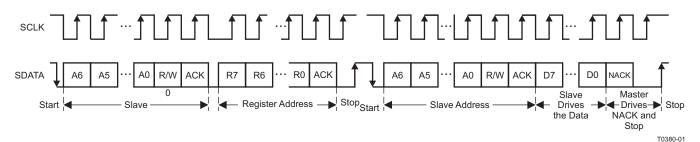


Figure 26. I²C-Bus Read From bq77PL900: Protocol B

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Register Set

The bq77PL900 has 12 addressable registers. These registers provide status, control, and configuration information for the battery protection system.

Table 10. Register Descriptions

| NAME | TEST PIN | ADDR | MEMORY | R/W | DESCRIPTION |
|------------------|-------------|------|--------|--------------------|--------------------------------------------------------------------------|
| STATUS | Х | 0x00 | Read | R | Status register |
| OUTPUT_CONTROL | Х | 0x01 | RAM | R/W | Output pin control from system host-control mode and external pin status |
| STATE_CONTROL | Х | 0x02 | RAM | R/W | State control from system host and external pin status |
| FUNCTION_CONTROL | Х | 0x03 | RAM | R/W | Function control from system host and external pin status |
| CELL BALANCE | Х | 0x04 | RAM | R/W | Battery cell select for balance bypass |
| CELL _SEL | Х | 0x05 | RAM | R/W | Battery cell select for balance bypass and for analog output voltage |
| OV CFG | Х | 0x06 | EEPROM | R/W ⁽¹⁾ | Overvoltage level and delay time register |
| UV LEVEL | Х | 0x07 | EEPROM | R/W ⁽¹⁾ | Undervoltage level register |
| OCV & UV DELAY | Х | 0x08 | EEPROM | R/W ⁽¹⁾ | Overload voltage level and undervoltage delay time register |
| OCDELAY | Х | 0x09 | EEPROM | R/W ⁽¹⁾ | Overload delay time register |
| SCD CFG | Х | 0x0a | EEPROM | R/W ⁽¹⁾ | Short-circuit in discharge current level and delay time register |
| EEPROM | Х | 0x0b | RAM | R/W | EEPROM read and write enable register |

⁽¹⁾ Write and read data will be match after write EEPROM writing procedure.

Table 11. Register Map

| NAME | | I ² C ADDR | B7 | В6 | В5 | B4 | В3 | B2 | B1 | В0 |
|----------------------------|------------------------------|-----------------------|--------|-----------|-------|--------|-------|-------|-------|-------|
| STATUS | | 0x00 | CHG | DSG | VGOOD | OVTEMP | UV | OV | OCD | SCD |
| OUTPUT_C | ONTROL | 0x01 | FS | PFALT | 0 | 0 | GPOD | CHG | DSG | LTCLR |
| STATE_CO | NTROL | 0x02 | IGAIN | VGAIN | 0 | 0 | 0 | 0 | HOST | SHDN |
| FUNCTION_ [Cell(9,10) b | _CONTROL alance register] | 0x03 | CBAL10 | CBAL9 | TOUT | BAT | PACK | IACAL | IAEN | VAEN |
| CELL_BALA | ANCE | 0x04 | CBAL8 | CBAL7 | CBAL6 | CBAL5 | CBAL4 | CBAL3 | CBAL2 | CBAL1 |
| CELL_SEL | | 0x05 | 0 | CAL2 | CAL1 | CAL0 | CELL4 | CELL3 | CELL2 | CELL1 |
| OV_CFG | | 0x06 | OVD2 | OVD1 | OVD0 | OVH1 | OVH0 | OV2 | OV1 | OV0 |
| UV_CFG | | 0x07 | 0 | UVFET_DIS | UVH1 | UVH0 | UV3 | UV2 | UV1 | UV0 |
| OCV&UV_D | ELAY | 0x08 | UVD3 | UVD2 | UVD1 | UVD0 | OCD3 | OCD2 | OCD1 | OCD0 |
| OCD_CFG | | 0x09 | CBEN | ZVC | SOR | OCDD4 | OCDD3 | OCDD2 | OCDD1 | OCDD0 |
| SCD_CFG | | 0x0a | SCDD3 | SCDD2 | SCDD1 | SCDD0 | SCD3 | SCD2 | SCD1 | SCD0 |
| | Read-writing | | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 0 |
| EEPROM | Writing (0x41) | 0x0b | 0 | 1 | 0 | 0 | 0 | 0 | 0 | 1 |
| | Reading (except above) | | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |



Register Control

0x01 to 0x05 should be controlled during host-control mode.

STATUS: Status Register

| | STATUS REGISTER (0x00) | | | | | | | |
|-----|------------------------|-------|--------|----|----|-----|-----|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| CHG | DSG | VGOOD | OVTEMP | UV | OV | OCD | SCD | |

The STATUS register provides information about the current state of the bq77PL900.

STATUS b0 (SCD): This bit indicates a short-circuit in discharge condition.

0 = Current is below the short-circuit in discharge threshold (default).

1 = Current is greater than or equal to the short-circuit in discharge threshold.

STATUS b1 (OCD): This bit indicates an overload condition.

0 = Current is less than or equal to the overload threshold (default).

1 = Current is greater than the overload threshold.

STATUS b2 (OV): This bit indicates an overvoltage condition.

0 = Voltage is less than or equal to the overvoltage threshold (default).

1 = Voltage is greater than the overvoltage threshold.

STATUS b3 (UV): This bit indicates an undervoltage condition.

0 = Voltage is greater than or equal to the undervoltage threshold (default).

1 = Voltage is less than the undervoltage threshold.

STATUS b4 (OVTEMP): This bit indicates an overtemperature condition.

0 = Temperature is lower than or equal to the overtemperature threshold (default).

1 = Temperature is higher than the overtemperature threshold.

STATUS b5 (VGOOD): This bit indicates a valid EEPROM power-supply voltage condition.

0 = Voltage is smaller than specified EEPROM power-supply voltage (default).

1 = Voltage is greater than or equal to the specified EEPROM power-supply voltage.

STATUS b6 (DSG): This bit reports the external discharge FET state.

0 = Discharge FET is off.

1 = Discharge FET is on.

STATUS b7 (CHG): This bit reports the external charge FET state.

0 = Charge FET is off.

1 = Charge FET is on.



OUTPUT_CONTROL: Output Control Register

| | OUTPUT_CONTROL REGISTER (0x01) | | | | | | | |
|----|--------------------------------|---|---|------|-----|-----|-------|--|
| 7 | 7 6 5 4 3 2 1 0 | | | | | | | |
| FS | PFALT | 0 | 0 | GPOD | CHG | DSG | LTCLR | |

The OUPTUT_CONTROL register controls some of the outputs of the bq77PL900 and can show the state of the external pin corresponding to the control.

OUTPUT_ CONTROL b0 (LTCLR): When a fault is latched, this bit releases the fault latch when toggled (default).

0→1→0 clears the fault latches, allowing STATUS to be cleared on its next read.

OUTPUT_ CONTROL b1 (DSG): This bit controls the external discharge FET.

- 0 = Discharge FET is OFF in host-control mode.
- 1 = Discharge FET is ON in host-control mode.

OUTPUT_ CONTROL b2 (CHG): This bit controls the external charge FET.

- 0 = Charge FET is OFF in host-control mode.
- 1 = Charge FET is ON in host-control mode.

OUTPUT_CONTROL b3 (GPOD): This bit enables or disables the GPOD output.

- 0 = GPOD output is high impedance (default).
- 1 = GPOD output is active (GND).

OUTPUT_CONTROL b6 (PFALT): This bit indicates a parity error in the EEPROM. This bit is read-only.

- 0 = No parity error (default)
- 1 = A parity error has occurred.

OUTPUT_CONTROL b7 (FS): This bit selects the undervoltage detection sampling time.

- 0 = Sampling time is 50 ms/cell (typ) (default).
- 1 = Sampling time is 100 μ s/cell (typ)

OUTPUT_CONTROL b6-b4: These bits are not used and should be set to 0.

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STATE_CONTROL: State Control Register

| | STATE_CONTROL REGISTER (0x02) | | | | | | | |
|-------|-------------------------------|---|---|---|---|------|------|--|
| 7 | 7 6 5 4 3 2 1 0 | | | | | | | |
| IGAIN | VGAIN | 0 | 0 | 0 | 0 | HOST | SHDN | |

The STATE_CONTROL register controls the states of the bq77PL900.

STATE_CONTROL b0 (SHDN): This bit enables or disables the shut down mode in host mode.

0 = Disable shutdown mode (default).

1 = Enable shutdown mode (if PACK voltage = 0 V).

STATE_CONTROL b1 (HOST): This bit selects stand-alone mode or host-control mode.

0 = Stand-alone mode (default)

1 = Host control mode

STATE_CONTROL b6 (VGAIN): This bit controls the cell amplifier scale.

0 = SCALE is 0.15 (default).

1 = SCALE is 0.2.

STATE_CONTROL b7 (IGAIN): This bit controls the current monitor amplifier gain.

0 = GAIN is 10 (default).

1 = GAIN is 50.

STATE_CONTROL b5-b2: These bits are not used and should be set to 0.



FUNCTION_CONTROL: Function Control Register, [Cell (9, 10) Balance Register]

| | FUNCTION CONTROL REGISTER (0x03) | | | | | | | |
|--------|----------------------------------|------|-----|------|-------|------|------|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
| CBAL10 | CBAL9 | TOUT | BAT | PACK | IACAL | IAEN | VAEN | |

The FUNCTION_CONTROL register controls some features of the bq77PL900.

FUNCTION CONTROL b0 (VAEN): This bit controls the internal cell-voltage amplifier.

- 0 = Disable cell-voltage amplifier (default).
- 1 = Enable cell-voltage amplifier.

FUNCTION _CONTROL b1 (IAEN): This bit controls the internal current-monitor amplifier.

- 0 = Disable current-monitor amplifier (default).
- 1 = Enable current-monitor amplifier.

FUNCTION_CONTROL b2 (IACAL): This bit controls the internal current-monitor amplifier offset-voltage output.

- 0 = Disable offset voltage output (default).
- 1 = Enable offset voltage output.

FUNCTION_CONTROL b3 (PACK): When VAEN = 1, PACK input is divided by 50 and presented on VCELL

- 0 = Disable pack total voltage output (default).
- 1 = Enable pack total voltage output.

FUNCTION CONTROL b4 (BAT): When VAEN = 1, BAT input is divided by 50 and presented on VCELL.

- 0 = Disable pack total voltage output (default).
- 1 = Enable pack total voltage output.

This bit priority is higher than PACK(b3).

FUNCTION _CONTROL b5 (TOUT): This bit controls the power to the thermistor.

- 0 = Thermistor power is off in host-control mode (default).
- 1 = Thermistor power is on in host-control mode.

FUNCTION _CONTROL b7-b6 (CELL10-9): This bit enables or disables the cell 9 and cell 10 balance charge bypass path

- 0 = Disable bottom series cell 9 or cell 10 balance charge bypass path (default).
- 1 = Enable bottom series cell 9 or cell 10 balance charge bypass path.



CELL BALANCE: Cell (1 to 8) Balance Register

| | CELL_BALANCE REGISTER (0x04) | | | | | | | | |
|-------|------------------------------|-------|-------|-------|-------|-------|-------|--|--|
| 7 | 7 6 5 4 3 2 1 0 | | | | | | | | |
| CBAL8 | CBAL7 | CBAL6 | CELL5 | CBAL4 | CBAL3 | CBAL2 | CBAL1 | | |

The CELL_BALANCE register controls cell balancing of the bq77PL900.

CELL BALANCE b7(CBAL8): This bit enables VC3-VC4 cell balance charge bypass path.

CELL_BALANCE b6(CBAL7): This bit enables VC4-VC5 cell balance charge bypass path.

CELL_BALANCE b5(CBAL6): This bit enables VC5-VC6 cell balance charge bypass path.

CELL_BALANCE b4(CBAL5): This bit enables VC6–VC7 cell balance charge bypass path.

CELL_BALANCE b3(CBAL4): This bit enables VC7–VC8 cell balance charge bypass path.

CELL_BALANCE b2(CBAL3): This bit enables VC8-VC9 cell balance charge bypass path.

CELL_BALANCE b1(CBAL2): This bit enables VC9-VC10 cell balance charge bypass path.

CELL_BALANCE b0(CBAL1): This bit enables VC10-VC11 cell balance charge bypass path.

0 = Disable series cell balance charge bypass path (default).

1 = Enable series cell balance charge bypass path.

CELL_SEL: Cell Translation Selection and Cell Translation Status Register

| | | | CELL_SEL RE | GISTER (0x05) | | | |
|---|------|------|-------------|---------------|-------|-------|-------|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| 0 | CAL2 | CAL1 | CAL0 | CELL4 | CELL3 | CELL2 | CELL1 |

The CELL_SEL register determines the cell selection for voltage measurement and translation. The register also determines operation mode of the cell voltage monitoring.

The CELL_SEL b6-b4 (CAL2-CAL0) bits should be 0 when VAEN(b0) in register 3 is changed from 0 to 1 or the VOUT pin will not go active.

This register is don't care when either BAT(b4) or PACK(b3) is set or VAEN(b0) is cleared in register 3.

CELL_SEL b3-b0 (CELL4-1): These four bits select the series cell for voltage measurement translation. These are don't care when CAL2-0 are not equal to 0x0.

| CELL4 | CELL3 | CELL2 | CELL1 | SELECTED CELL |
|-------|-------|-------|-------|--------------------------------------------|
| 0 | 0 | 0 | 0 | VC10–VC11, Bottom series element (default) |
| 0 | 0 | 0 | 1 | VC9-VC10, Second-lowest series element |
| 0 | 0 | 1 | 0 | VC8-VC9, Third-lowest series element |
| 0 | 0 | 1 | 1 | VC7-VC8, Fourth-lowest series element |
| 0 | 1 | 0 | 0 | VC6-VC7, Fifth-lowest series element |
| 0 | 1 | 0 | 1 | VC5–VC6, Sixth-highest series element |
| 0 | 1 | 1 | 0 | VC4–VC5, Seventh-highest series element |
| 0 | 1 | 1 | 1 | VC3-VC4, Eighth-highest series element |
| 1 | 0 | 0 | 0 | VC2-VC3, Ninth-highest series element |
| 1 | 0 | 0 | 1 | VC1-VC2, Top series element |
| | Other | | | VC10–VC11, Bottom series element |



CELL_SEL b6-b4 (CAL2-0): These three bits determine the mode of the voltage monitor block.

| CAL2 | CAL1 | CAL0 | SELECTED MODE |
|------|------|------|--------------------------------------------------------------------------------------------------------|
| 0 | 0 | 0 | Cell translation for selected cell (default), VOUT output depends on CELL4-1. |
| 0 | 0 | 1 | Monitor offset of differential amplifier (both inputs of differential amplifier are connected to GND). |
| 0 | 1 | 0 | Monitor the scaled V _{REF} ⁽¹⁾ value. |
| 0 | 1 | 1 | Monitor V _{REF} ⁽¹⁾ directly. |
| 1 | 0 | 0 | Monitor the scaled 2.5-V value to the measured 2.5 V. |
| 1 | 0 | 1 | Monitor V _{REF} –0 V, through the sample-and-hold circuit. (1) |
| 1 | 1 | 0 | Monitor 2.5 V-0 V through the sample-and-hold circuit. |
| 1 | 1 | 1 | Monitor 2.5 V–1.2 V through the sample-and-hold circuit. |

⁽¹⁾ When VGAIN = 0, VREF = 0.975 V; when VGAIN = 1, VREF = 1.2 V.

CELL_SEL b7: These bits are not used and should be set to 0.

OV_CFG: Overvoltage Delay Time, Hysteresis, and Threshold Configuration Register

| | OV CFG REGISTER (0x06) | | | | | | | | | |
|------|------------------------|------|------|------|-----|-----|-----|--|--|--|
| 7 | 7 6 5 4 3 2 1 0 | | | | | | | | | |
| OVD2 | OVD1 | OVD0 | OVH1 | OVH0 | OV2 | OV1 | OV0 | | | |

The OV register determines cell overvoltage threshold, hysteresis voltage, and detection delay time.

OV_CFG b2-b0 (OV2-0) configuration bits with corresponding voltage threshold with a default of 000. Resolution is 50 mV.

| 0x00 | 4.15 V | 0x02 | 4.25 V | 0x04 | 4.35 V | 0x06 | 4.45 V |
|------|--------|------|--------|------|--------|------|--------|
| 0x01 | 4.2 V | 0x03 | 4.3 V | 0x05 | 4.4 V | 0x07 | 4.5 V |

OV_CFG b4-b3 (OVH1-0) configuration bits with corresponding hysteresis voltage with a default of 00. Resolution is 100 mV.

| 0x00 | 0.1 V | 0x01 | 0.2 V | 0x02 | 0.3 V | 0x03 | 0 V |
|------|-------|------|-------|------|-------|------|-----|

OV_CFG b7-b5 (OVD2-0) configuration bits with corresponding delay time for overvoltage with a default of 000. Resolution is 250 ms.

| 0x00 | 0.5 s | 0x02 | 1 s | 0x04 | 1.5 s | 0x06 | 2 s |
|------|--------|------|--------|------|--------|------|--------|
| 0x01 | 0.75 s | 0x03 | 1.25 s | 0x05 | 1.75 s | 0x07 | 2.25 s |

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UV CFG: Undervoltage Hysteresis and Threshold Configuration Register

| UV LEVEL REGISTER (0x07) | | | | | | | | | |
|--------------------------|----------|------|------|-----|-----|-----|-----|--|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | |
| 0 | UVFETDIS | UVH1 | UVH0 | UV3 | UV2 | UV1 | UV0 | | |

The UV register determines the cell undervoltage threshold, hysteresis voltage, and detection delay time.

UV_CFG b2-b0 (UV3-0) configuration bits with corresponding voltage threshold with a default of 000. Resolution is 100 mV.

| 0x00 | 1.4 V | 0x04 | 1.8 V | 0x08 | 2.2 V | 0x0c | 2.6 V |
|------|-------|------|-------|------|-------|------|-------|
| 0x01 | 1.5 V | 0x05 | 1.9 V | 0x09 | 2.3 V | 0x0d | 2.7 V |
| 0x02 | 1.6 V | 0x06 | 2 V | 0x0a | 2.4 V | 0x0e | 2.8 V |
| 0x03 | 1.7 V | 0x07 | 2.1 V | 0x0b | 2.5 V | 0x0f | 2.9 V |

UV_CFG b5-b4 (UVH1-0) configuration bits with corresponding hysteresis voltage with a default of 00. Resolution is 200 mV.

| 0x00 | 0.2 V | 0x01 | 0.4 V | 0x02 | 0.8 V | 0x03 | 1.2 V |
|------|-------|------|-------|------|-------|------|-------|

When the undervoltage threshold and the hysteresis values are high, then undervoltage recovery may not occur. To avoid this, Table 12 should be used for assistance in configuration.

Table 12. Combination of UV Release Voltage vs Hysteresis

| | | | HYST | ERESIS | |
|------------------------|-----|-------|-------|--------|-------|
| | | 0.2 V | 0.4 V | 0.8 V | 1.2 V |
| | 1.4 | 1.6 | 1.8 | 2.2 | 2.6 |
| | 1.5 | 1.7 | 1.9 | 2.3 | 2.7 |
| | 1.6 | 1.8 | 2 | 2.4 | 2.8 |
| | 1.7 | 1.9 | 2.1 | 2.5 | 2.9 |
| | 1.8 | 2 | 2.2 | 2.6 | 3 |
| | 1.9 | 2.1 | 2.3 | 2.7 | 3.1 |
| | 2 | 2.2 | 2.4 | 2.8 | 3.2 |
| Cell undervoltage (V) | 2.1 | 2.3 | 2.5 | 2.9 | 3.3 |
| Cell dildervoltage (v) | 2.2 | 2.4 | 2.6 | 3 | 3.3 |
| | 2.3 | 2.5 | 2.7 | 3.1 | 3.3 |
| | 2.4 | 2.6 | 2.8 | 3.2 | 3.3 |
| | 2.5 | 2.7 | 2.9 | 3.3 | 3.3 |
| | 2.6 | 2.8 | 3 | 3.3 | 3.3 |
| | 2.7 | 2.9 | 3.1 | 3.3 | 3.3 |
| | 2.8 | 3 | 3.2 | 3.3 | 3.3 |
| | 2.9 | 3.1 | 3.3 | 3.3 | 3.3 |

UV_CFG b6 (UVFET_DIS): This bit disable automatically turns off the DSG output when UV is detected in host-control mode.

0 = DSG output changes to OFF when UV is detected (default).

1 = DSG output does not change to OFF when UV is detected.But the UV bit of the status register (0x00) is changed, even if this bit = 1.

UV_CFG b7: This bit should be set to 0, so that the bq77PL900 protects battery cell safety.



OC&UV_DELAY: Overcurrent and Undervoltage Delay Register

| | | OC&UVDELAY REGISTER (0x08) | | | | | | | | | |
|-----------------|------|----------------------------|------|------|------|------|------|------|--|--|--|
| 7 6 5 4 3 2 1 0 | | | | | | | | 0 | | | |
| | UVD3 | UVD2 | UVD1 | UVD0 | OCD3 | OCD2 | OCD1 | OCD0 | | | |

The FUNCTION and OCDV CFG register determines overcurrent in discharge voltage threshold and controls functions.

OC&UV_DELAY b3-b0 (OCD3-0) configuration bits with corresponding voltage threshold. Resolution is 5 mV.

| 0x00 | 10 mV | 0x04 | 30 mV | 0x08 | 50 mV | 0x0c | 70 mV |
|------|-------|------|-------|------|-------|------|-------|
| 0x01 | 15 mV | 0x05 | 35 mV | 0x09 | 55 mV | 0x0c | 75 mV |
| 0x02 | 20 mV | 0x06 | 40 mV | 0x0a | 60 mV | 0x0e | 80 mV |
| 0x03 | 25 mV | 0x07 | 45 mV | 0x0b | 65 mV | 0x0f | 85 mV |

OC&UVDELAY b7-hb4 (UVD3-0) configuration bits with corresponding delay time for undervoltage with a default of 000. Resolution is 1 s when the FS bit = 0.

| OC&UVDELAY | FS bit (OUTPUT_C | ONTROL b7) |
|----------------|--------------------------|------------|
| b7-b4 (UVD3-0) | 1 | 0 |
| 0x00 | See the following table. | 1 s |
| 0x01 | | 2 s |
| 0x02 | | 3 s |
| 0x03 | | 4 s |
| 0x04 | | 5 s |
| 0x05 | | 6 s |
| 0x06 | | 7 s |
| 0x07 | | 8 s |
| 0x08 | 1 s | 1 s |
| 0x09 | 2 s | 2 s |
| 0x0a | 3 s | 3 s |
| 0x0b | 4 s | 4 s |
| 0x0c | 5 s | 5 s |
| 0x0d | 6 s | 6 s |
| 0x0e | 7 s | 7 s |
| 0x0f | 8 s | 8 s |

| LIV(D. 2-0- | Internal Count | | DELAY TIME (ms), FS = 1 | | | | | | |
|-------------|----------------|---------|-------------------------|---------|---------|---------|----------|--|--|
| UVD<3:0> | Internal Count | 5 Cells | 6 Cells | 7 Cells | 8 Cells | 9 Cells | 10 Cells | | |
| 0x00 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | | |
| 0x01 | 2 | 1.25 | 1.5 | 1.75 | 2 | 2.25 | 2.5 | | |
| 0x02 | 4 | 2.5 | 3 | 3.5 | 4 | 4.5 | 5 | | |
| 0x03 | 8 | 5 | 6 | 7 | 8 | 9 | 10 | | |
| 0x04 | 10 | 6.25 | 7.5 | 8.75 | 10 | 11.25 | 12.5 | | |
| 0x05 | 12 | 7.5 | 9 | 10.5 | 12 | 13.5 | 15 | | |
| 0x06 | 16 | 10 | 12 | 14 | 16 | 18 | 20 | | |
| 0x07 | 24 | 15 | 18 | 21 | 24 | 27 | 30 | | |

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OCD_CFG: Overcurrent in Discharge Configuration Register

| | OCD_CFG REGISTER (0x09) | | | | | | | | | |
|------|-------------------------|-----|-------|-------|-------|-------|-------|--|--|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | |
| CBEN | ZVC | SOR | OCDD4 | OCDD3 | OCDD2 | OCDD1 | OCDD0 | | | |

The FUNCTION & OCD_CFG register determines function and overload-detection delay time.

OCD_CFG b4-b0 (OCDD4-0) configuration bits with corresponding delay time. Units are in ms and resolution is 20 ms or 100 ms.

| 0x00 | 20 ms | 0x08 | 180 ms | 0x10 | 100 ms | 0x18 | 900 ms | |
|------|--------|------|--------|------|--------|------|---------|--|
| 0x01 | 40 ms | 0x09 | 200 ms | 0x11 | 200 ms | 0x19 | 1000 ms | |
| 0x02 | 60 ms | 0x0a | 220 ms | 0x12 | 300 ms | 0x1a | 1100 ms | |
| 0x03 | 80 ms | 0x0b | 240 ms | 0x13 | 400 ms | 0x1b | 1200 ms | |
| 0x04 | 100 ms | 0x0c | 260 ms | 0x14 | 500 ms | 0x1c | 1300 ms | |
| 0x05 | 120 ms | 0x0d | 280 ms | 0x15 | 600 ms | 0x1d | 1400 ms | |
| 0x06 | 140 ms | 0x0e | 300 ms | 0x16 | 700 ms | 0x1e | 1500 ms | |
| 0x07 | 160 ms | 0x0f | 320 ms | 0x17 | 800 ms | 0x1f | 1600 ms | |

OCD_CFG b5 (SOR): Recover condition from SC and OC with stand-alone mode

- 0 = Recover by attaching a charger. Recover comparator is active after 12.8 s for OC/SC detection (default).
- 1 = Recover by SC/OC condition released. Recovery from OC/SC after 12.8 s.

OCD_CFG b6 (ZVC): This bit controls the 0-V/precharge of the GPOD output.

- 0 = Disable the GPOD output 0-V/precharge mode with stand-alone (default).
- 1 = Enable the GPOD output 0-V/precharge mode with stand-alone.

OCD_CFG b7 (CBEN): This bit controls cell balancing.

- 0 = Disable the cell balancing function (default)
- 1 = Enable the cell balancing function.



SCD CFG: Short-Circuit in Discharge Configuration Register

| | SCD_CFG REGISTER (0x0a) | | | | | | | | | |
|-------|-------------------------|-------|-------|------|------|------|------|--|--|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | |
| SCDD3 | SCDD2 | SCDD1 | SCDD0 | SCD3 | SCD2 | SCD1 | SCD0 | | | |

The SCD CFG register determines the short-circuit voltage threshold and detection delay time.

SCD_CFG b3-b0 (SCD3-0): These lower-nibble bits select the value of the short-circuit in discharge voltage threshold with 0000 as the default, units in mV, and a resolution of 5 mV.

| 0x00 | 60 mV | 0x04 | 80 mV | 0x08 | 100 mV | 0x0c | 120 mV |
|------|-------|------|-------|---------------------|--------|--------|--------|
| 0x01 | 65 mV | 0x05 | 85 mV | mV 0x09 105 mV 0x0d | | 125 mV | |
| 0x02 | 70 mV | 0x06 | 90 mV | 0x0a | 110 mV | 0x0e | 130 mV |
| 0x03 | 75 mV | 0x07 | 95 mV | 0x0b | 115 mV | 0x0f | 135 mV |

SCD_CFG b7-b4 (SCDD3-0): These upper nibble bits select the value of the short circuit in discharge delay time. 0000 is the default, units of us and a resolution of 60us.

| 0x00 | 0 μs | 0x04 | 240 μs | 0x08 | 480 μs | 0x0c | 720 μs | |
|------|--------|------|--------|------|--------|------|--------|--|
| 0x01 | 60 μs | 0x05 | 300 μs | 0x09 | 540 μs | 0x0d | 780 μs | |
| 0x02 | 120 μs | 0x06 | 360 μs | 0x0a | 600 μs | 0x0e | 840 μs | |
| 0x03 | 180 μs | 0x07 | 420 μs | 0x0b | 660 μs | 0x0f | 900 μs | |

EEPROM: EEPROM Write Enable and Configuration Register

| | EEPROM REGISTER (0x0b) | | | | | | | | | | |
|---------|------------------------|---------|---------|---------|---------|---------|---------|--|--|--|--|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | | | | |
| EEPROM7 | EEPROM6 | EEPROM5 | EEPROM4 | EEPROM3 | EEPROM2 | EEPROM1 | EEPROM0 | | | | |

EEPROM b7-b0 (EEPROM7-0):

These bits enable data write to EEPROM(0x06-0x9a) with 0100 0001 (0x41).

Prewriting data is available by setting these bits with 0110 0010 (0x62).

Default is 0000 0000 (0x00).

Zero-Volt Charging

In order to charge cells, the CHG FET must be turned on to create a current path. When the battery voltage (V_{BAT}) is low and the CHG is ON, the pack voltage (V_{PACK}) is as low as the battery voltage. In cases where the level is below the supply voltage for the bq77PL900 is too low to operate, there are two configurations to provide the appropriate 0-V/precharge function.

Common FET mode does not require a dedicated 0-V/precharge FET. The CHG FET is ON. This method is suitable for a charger that has a 0-V/precharge function. The second mode is to use a 0-V/precharge FET which establishes a dedicated 0-V/precharge current path by using an additional open drain (GPOD output) for driving an external FET (PCHG FET). This configuration sustains the PACK+ voltage level. Any type of charger can be used with this configuration.

Table 13. 0-V Charge Summary

| PROTECTION MODE | 0-V CHARGE TYPE | DEMANDED CHARGE FUNCTION | APPLICATION CIRCUIT |
|-------------------|-----------------------|--------------------------|------------------------------------------------------------|
| Host-control mode | Common FET (1) | Fast charge Precharge | PMS = PACK GPOD output not used |
| | 0-V/precharge FET (2) | Fast charge | PMS = GND GPOD output: Drives 0-V charge FET (PCHG FET) |
| Stand-alone mode | Common FET (1) | Fast charge Precharge | PMS = PACK GPOD output not used |
| | 0-V/precharge FET (2) | Fast charge | PMS = GND GPOD output: Drives 0-V charge FET (PCHG FET) |

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Common FET

In this mode, the PMS pin is connected to PACK+. In this configuration, the charger must have a 0-V/precharging function which is typically controlled as follows:

- The cell voltage is lower than a certain constant voltage (normally about 3 V/cell).
 - Apply 0-V/precharging current.
- The cell voltage is higher than a certain constant voltage (normally about 3 V/cell).
 - Apply fast-charging current.

When the charger is connected and VPMS is greater than or equal to 0.7 V, the CHG FET is turned ON. The charging current flows through the CHG FET and the back diode of the DSG.

V_{PACK+} = V_{BAT} + 0.7 V (VF: forward voltage of a DSG-FET back diode) + V_{DS}(CHG-FET)

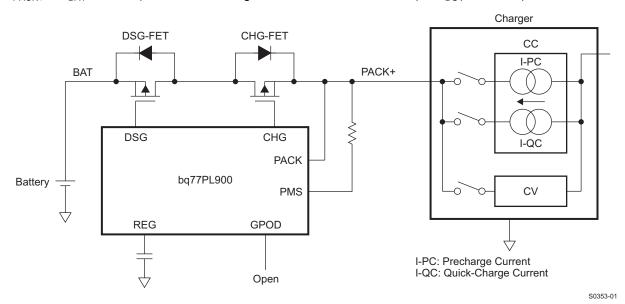


Figure 27. Common FET Circuit Diagram

When the PACK pin voltage is maintained at higher than 0.7 V and the precharging current is maintained, the PACK voltage and BAT voltage are under the minimum bq77PL900 supply voltage, so the regulator is inactive.

When the BAT voltage rises and the PACK pin voltage reaches the bq77PL900 minimum supply voltage, an internal 3.3-V regulator is turned ON. Then, the CHG FET state is controlled by UVP and OVP functions. When the all the cell voltages reach fast-charge voltage (about 3 V per cell), the charger starts the fast-charging mode.

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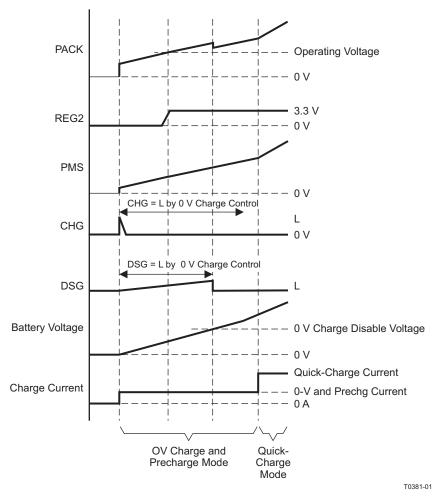


Figure 28. Signal Timing of Pins During 0-V/Precharging

8.22.2 0-V/Precharge FET in Host Control Mode

In this configuration, the charger does not have a requirement to support a precharge function. Thus, the host controller and bq77PL900 must limit the fast charging current to a suitable 0-V/precharge level.

The PMS pin is connected to GND and a 0-V/precharge current flows through a dedicated 0-V/precharge FET (PCHG FET).



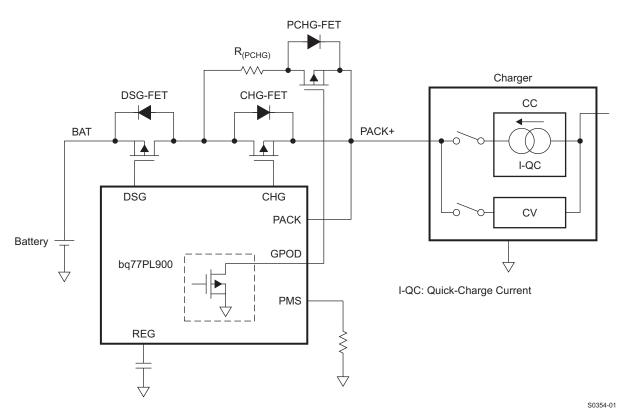


Figure 29. 0-V/Precharge FET Circuit in Host-Control Mode

The 0-V/precharge FET is driven by the GPOD output. By setting the GPOD bit to 1, the GPOD output turns ON, and then the PCHG FET. The 0-V/precharge current is limited by the 0-V/precharge FET (PCHG FET) and a series resistor (R(PCHG)) as follows.

$$I_{OV/PCHG} = I_D = (V_{PACK+} - V_{BAT} - V_{DS}) / R_P$$

A load curve of the PCHG FET is shown in Figure 30. When the gate-source voltage (V_{DS}) is high enough, the FET operates in the linear region and has low resistance. By approximating V_{DS} as 0 V, the 0-V/precharge current ($I_{OV/PCHG}$) is expressed as follows.

$$I_{OV/PCHG} = (V_{PACK+} - V_{BAT}) / R_{P}$$

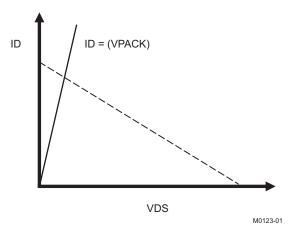


Figure 30. 0V/PCHG FET ID and VDS Characteristics



During the 0-V/precharge, the CHG FET is turned OFF and the PCHG FET is turned ON. When the host controller detects that all the cell voltages have reached the fast-charge threshold, it then turns ON the CHG FET and turns OFF the PCHG FET. The signal timing is shown in Figure 31.

The CHG, DSG and PCHG FETs are turned OFF when the charger is connected. Then, the charger applies its maximum output voltage (constant-voltage-mode output voltage) to the PACK+ pin. Then, the bq77PL900 3.3-V regulator becomes active and supplies power to the host controller. As the host controller starts up, it turns on the GPOD output and the 0-V/precharge current begins to flow.

In this configuration, attention is needed to control high power consumption at the PCHG FET and the series resistor (R_P). The highest power is consumed at 0-V cell voltage (highest voltage between PACK+ and BAT pins) and it results in highest heat generation. For example, the power consumption in 10 series batteries with 42-V fast charge voltage and 1-k Ω R_P is expressed as follows.

$$I_{OV/PCHG}$$
 = (42 V - 0 V) /1 k Ω = 42 mA (Power consumption at R_D) = 42 V × 42 mA = 1.6 W

It is recommended to combine the resistor (R_P) and the thermistor to reduce the consumption. Once the cell voltage reaches the fast-charge threshold, the host controller turns ON the CHG and DSG FETs and also turns OFF the PCHG FET.

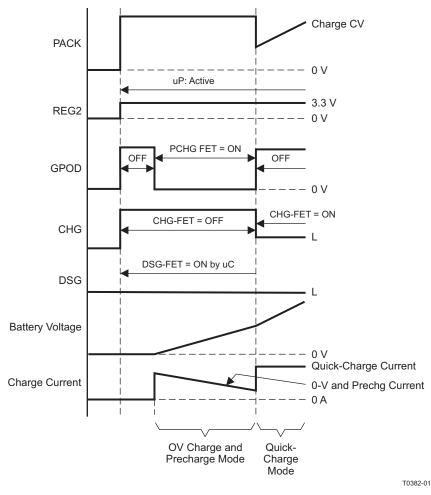


Figure 31. Signal Timing of Pins During 0-V Charging and Precharging (Precharge FET) With Host-Control Mode



0-V/Precharge FER in Stand-Alone Mode

The circuit configuration is the same as 0-V/precharge FET in host-control mode, although in stand-alone mode the bq77PL900 automatically turns on the GPOD output. When the battery voltage reaches 0 V, the charger disable voltage (= PMS disable voltage), the GPOD output is turned OFF, and then the DSG and CHG FETs are controlled by an internal UV comparator function. To activate this mode, set *OCDELAY register [ZVC]*.

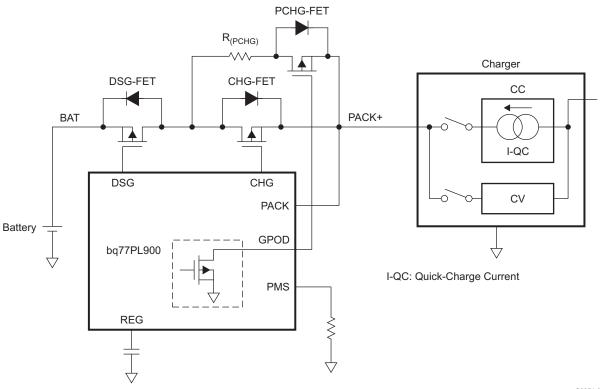


Figure 32. 0-V/Precharge FET Circuit Diagram In Stand-Alone Mode

S0354-01



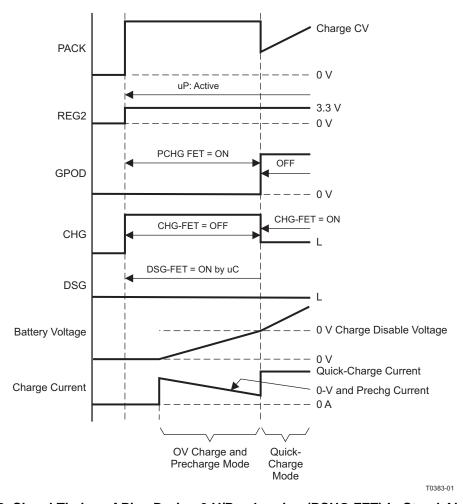


Figure 33. Signal Timing of Pins During 0-V/Precharging (PCHG FET) In Stand-Alone Mode



PACKAGE OPTION ADDENDUM

6-Feb-2020

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|--------------------|------|----------------|----------------------------|------------------|---------------------|--------------|----------------|---------|
| BQ77PL900DL | ACTIVE | SSOP | DL | 48 | 25 | Green (RoHS & no Sb/Br) | NIPDAU | Level-2-260C-1 YEAR | -40 to 100 | BQ77PL900 | Samples |
| BQ77PL900DLR | ACTIVE | SSOP | DL | 48 | 1000 | Green (RoHS & no Sb/Br) | NIPDAU | Level-2-260C-1 YEAR | -40 to 100 | BQ77PL900 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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6-Feb-2020

PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

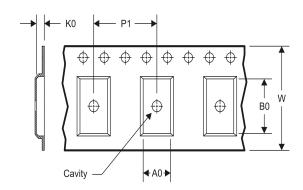
TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



| A0 | Dimension designed to accommodate the component width |
|----|-----------------------------------------------------------|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

TAPE AND REEL INFORMATION

*All dimensions are nominal

| Device | Package Type | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| BQ77PL900DLR | SSOP | DL | 48 | 1000 | 330.0 | 32.4 | 11.35 | 16.2 | 3.1 | 16.0 | 32.0 | Q1 |

PACKAGE MATERIALS INFORMATION

www.ti.com 14-Jul-2012



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) | |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|--|
| BQ77PL900DLR | SSOP | DL | 48 | 1000 | 367.0 | 367.0 | 55.0 | |

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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